

CMOS 16-Bit Microcontrollers

TMP95FW54AF

1. Outline and Features

TMP95FW54A is a high-speed 16-bit microcontroller designed for the control of various mid- to large-scale equipment.

TMP95FW54A comes in a 100-pin flat package.

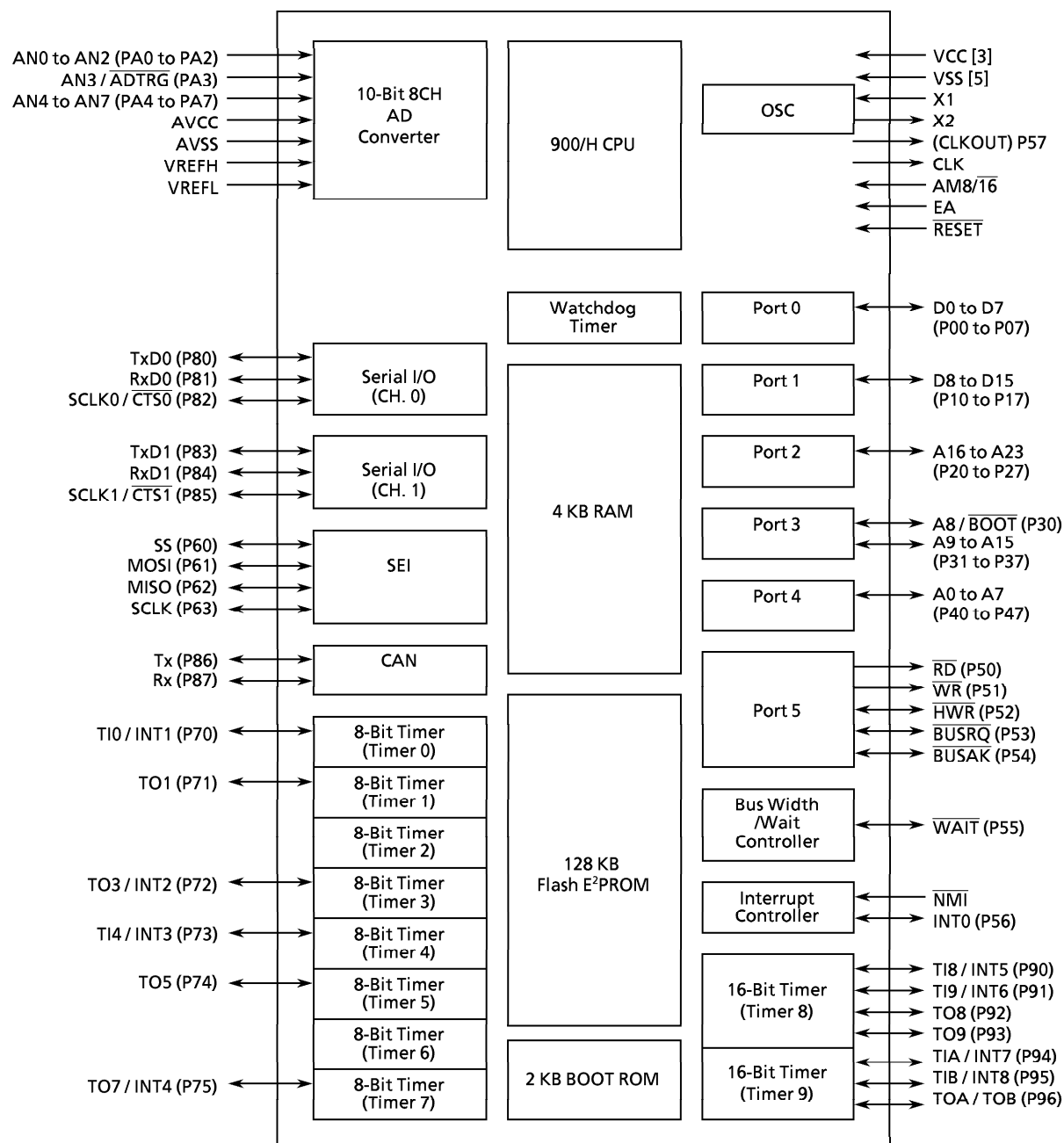
Listed below are the features.

- (1) High-speed 16-bit CPU (900/H CPU)
 - Instruction mnemonics are upward-compatible with TLCS-90/900
 - 16M bytes of linear address space
 - General-purpose registers and register banks
 - 16-bit multiplication and division instructions; bit transfer and arithmetic instructions
 - Micro DMA: Four-channels (667 ns/2 bytes at 24 MHz)
- (2) Minimum instruction execution time: 167 ns (at 24 MHz)
- (3) Built-in RAM: 4 Kbytes
Built-in ROM: 128 Kbyte Flash E²PROM
2 Kbyte mask ROM (used for booting)
- (4) External memory expansion
 - Expandable up to 16 Mbytes (shared program/data area)
 - External data bus width select pin (AM8/T₁₆)
 - Can simultaneously support 8/16-bit width external data bus ... Dynamic data bus sizing
- (5) 8-bit timers: 8 channels
 - With event counter function: 2 channels
- (6) 16-bit timer/event counter: 2 channels
- (7) General-purpose serial interface: 2 channels
- (8) Serial Expansion Interface: 1 channel
- (9) CAN Controller: 1 channel

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- (10) 10-bit AD converter: 8 channels
- (11) Watchdog timer
- (12) Bus width/wait controller: 4 blocks
- (13) Interrupts: 49 interrupts
 - 9 CPU interrupts: Software interrupt instruction and illegal instruction
 - 30 internal interrupts:
 - 10 external interrupts:] Seven selectable priority levels
- (14) Input/output ports: 81 pins
- (15) Standby mode
 - Four HALT modes: RUN, IDLE2, IDLE1, STOP
- (16) Operating voltage
 - $V_{CC}=4.5$ to 5.5 V
- (17) Package
 - P-QFP100-1414-0.50E



Note: After a reset, functions in parentheses () are selected for the shared pins.

Figure 1.1 TMP95FW54A Block Diagram

2. Pin Assignment and Pin Functions

This section shows the TMP95FW54AF pin assignment, and the names and an outline of the functions of the input/output pins.

2.1 Pin Assignment Diagram

Figure 2.1.1 is a pin assignment diagram for TMP95FW54AF.

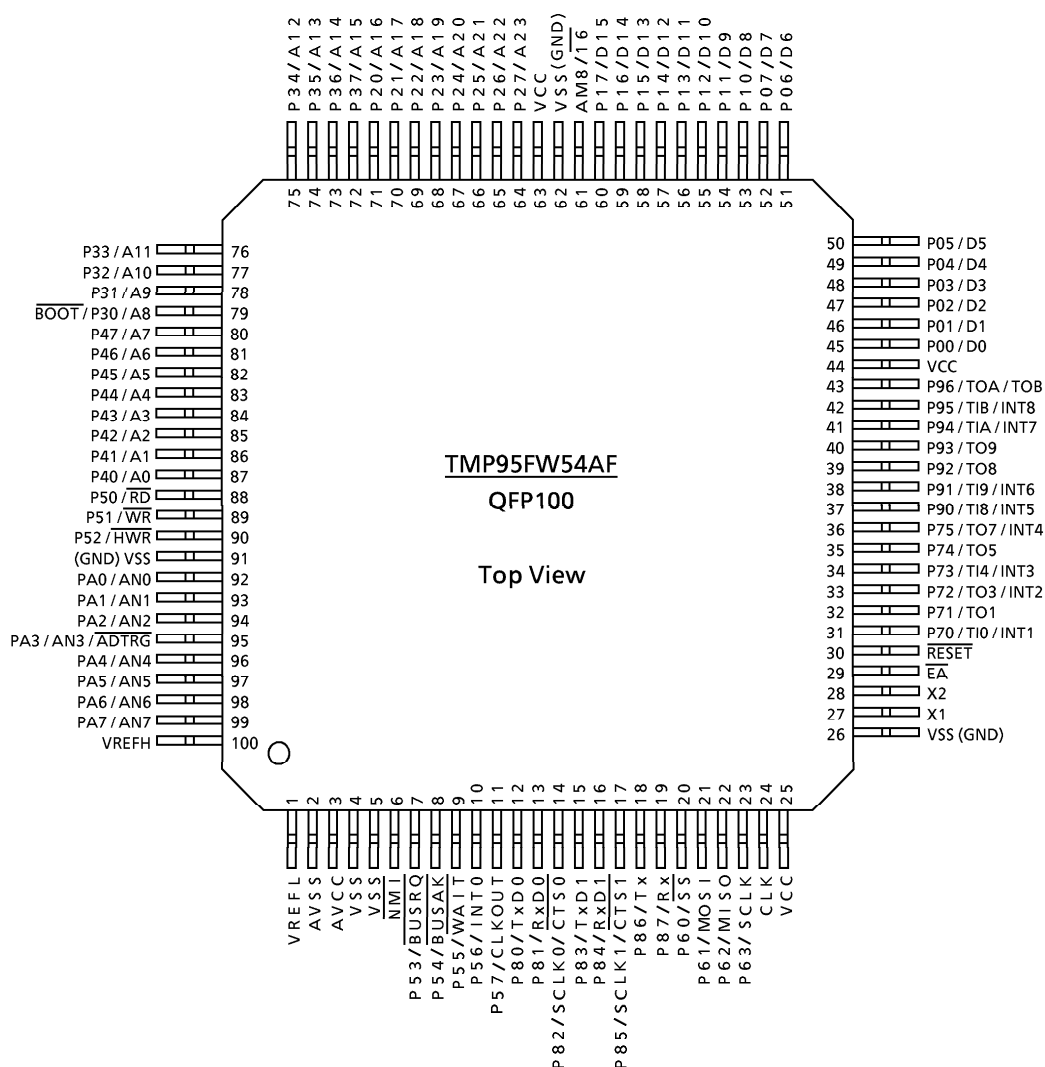


Figure 2.1.1 Pin assignment diagram (100-Pin QFP)

2.2 Pin Names and Functions

Table 2.2.1 shows the names and functions of the input/output pins.

Table 2.2.1 Pin names and functions (1/4)

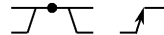
Pin Name	Number of Pins	Input/Output	Function
P00 to P07 / D0 to D7	8	Input/output	Port 0: I/O port. Input or output specifiable in units of bits
		Input/output	Data: Data bus 0 to 7
P10 to P17 / D8 to D15	8	Input/output	Port 1: I/O port. Input or output specifiable in units of bits
		Input/output	Data: Data bus 8 to 15
P20 to P27 / A16 to A23	8	Input/output	Port 2: I/O port. Input or output specifiable in units of bits
		Output	Address: Address bus 16 to 23
P30 / A8 / $\overline{\text{BOOT}}$	1	Input/output	Port 30: I/O port (with built-in pull-up resistor during input mode.)
		Output	Address: Address bus 8
		Input	Single boot mode setting. Pulled up during reset.
P31 to P37 / A9 to A15	7	Input/output	Port 31 to 37: I/O port. Input or output specifiable in units of bits
		Output	Address: Address bus 9 to 15
P40 to P47 / A0 to A7	8	Input/output	Port 4: I/O port. Input or output specifiable in units of bits
		Output	Address: Address bus 0 to 7
P50 / $\overline{\text{RD}}$	1	Output	Port 50: Output-only port
		Output	Read: Outputs strobe signal to read external memory (setting P5 <P50> = 0 and P5FC <P50F> = 1 outputs strobe signal at all read timings)
P51 / $\overline{\text{WR}}$	1	Output	Port 51: Output-only port.
		Output	Write: Outputs strobe signal to write data on pins D0 to D7
P52 / $\overline{\text{HWR}}$	1	Input/output	Port 52: I/O port (with built-in pull-up resistor)
		Output	Upper write: Outputs strobe signal to write data on pins D8 to D15
P53 / $\overline{\text{BUSRQ}}$	1	Input/output	Port 53: I/O port (with built-in pull-up resistor)
		Input	Bus request: Input pin to request external bus release
P54 / $\overline{\text{BUSAK}}$	1	Input/output	Port 54: I/O port (with built-in pull-up resistor)
		Output	Bus acknowledge: Output pin to acknowledge that CPU received $\overline{\text{BUSRQ}}$ and released external bus.
P55 / $\overline{\text{WAIT}}$	1	Input/output	Port 55: I/O port (with built-in pull up resistor)
		Input	Wait: Buswait request pin for CPU (Effective when 1 WAIT + N mode, or 0 + N WAIT mode. Set using bus width/wait control register.)
P56 / INT0	1	Input/output	Port 56: I/O port (with built-in pull-up resistor)
		Input	Interrupt request pin 0: Interrupt request pin with programmable level/rising edge. 

Table 2.2.1 Pin names and functions (2/4)





Pin Name	Number of Pins	Input/Output	Function
P57 / CLKOUT	1	Output	Port 57: Output-only port (with built-in pull-up resistor)
		Output	CLKOUT output: Outputs external clock divided by 6. Pulled up during reset.
P60 / \overline{SS}	1	Input/output	Port 60: I/O port
		Input	SEI slave select input
P61 / MOSI	1	Input/output	Port 61: I/O port
		Input/output	SEI master output, slave input
P62 / MISO	1	Input/output	Port 62: I/O port
		Input/output	SEI master input, slave output
P63 / SCLK	1	Input/output	Port 63: I/O port
		Input/output	SEI clock input/output
P70 / TI0 / INT1	1	Input/output	Port 70: I/O port
		Input	Timer input 0: Input pin for timer 0
		Input	Interrupt request pin 1: Rising-edge interrupt request pin 
P71 / TO1	1	Input/output	Port 71: I/O port.
		Output	Timer output 1: Output pin for timer 0 or 1
P72 / TO3 / INT2	1	Input/output	Port 72: I/O port
		Output	Timer output 3: Output pin for timer 2 or 3
		Input	Interrupt request pin 2: Rising-edge interrupt request pin 
P73 / TI4 / INT3	1	Input/output	Port 73: I/O port
		Input	Timer input 4: Input pin for timer 4
		Input	Interrupt request pin 3: Rising-edge interrupt request pin 
P74 / TO5	1	Input/output	Port 74: I/O port
		Output	Timer output 5: Output pin for timer 4 or 5
P75 / TO7 / INT4	1	Input/output	Port 75: I/O port
		Output	Timer output 7: Output pin for timer 6 or 7
		Input	Interrupt request pin 4: Rising-edge interrupt request pin 
P80 / TxD0	1	Input/output	Port 80: I/O port (with built-in pull-up resistor)
		Output	Serial transmission data 0
P81 / RxD0	1	Input/output	Port 81: I/O port (with built-in pull-up resistor)
		Input	Serial receive data 0
P82 / SCLK0 / $\overline{CTS0}$	1	Input/output	Port 82: I/O port (with built-in pull-up resistor)
		Input/output	Serial clock input/output 0
		Input	Serial data ready to send 0 (Clear-to-send)

Table 2.2.1 Pin names and functions (3/4)

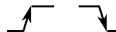

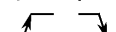

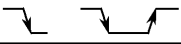
Pin Name	Number of Pins	Input/Output	Function
P83 / TxD1	1	Input/output	Port 83: I/O port (with built-in pull-up resistor)
		Output	Serial transmission data 1
P84 / RxD1	1	Input/output	Port 84: I/O port (with built-in pull-up resistor)
		Input	Serial receive data 1
P85 / SCLK1 / $\overline{\text{CTS1}}$	1	Input/output	Port 85: I/O port (with built-in pull-up resistor)
		Input/output	Serial clock input/output 1
		Input	Serial data ready to send 1 (Clear-to-send)
P86 / Tx	1	Input/output	Port 86: I/O port (with built-in pull-up resistor)
		Output	CAN transmission data
P87 / Rx	1	Input/output	Port 87: I/O port (with built-in pull-up resistor)
		Input	CAN receive data
P90 / TI8 / INT5	1	Input/output	Port 90: I/O port
		Input	Timer input 8: Input pin for timer 8
		Input	Interrupt request pin 5: Interrupt request pin with programmable rising/falling edge 
P91 / TI9 / INT6	1	Input/output	Port 91: I/O port
		Input	Timer input 9: Input pin for timer 8
		Input	Interrupt request pin 6: Rising edge interrupt request pin 
P92 / TO8	1	Input/output	Port 92: I/O port
		Output	Timer output 8: Output pin for timer 8
P93 / TO9	1	Input/output	Port 93: I/O port
		Output	Timer output 9: Output pin for timer 8
P94 / TIA / INT7	1	Input/output	Port 94: I/O port
		Input	Timer input A: Input pin for timer 9
		Input	Interrupt request pin 7: Interrupt request pin with programmable rising/falling edge 
P95 / TIB / INT8	1	Input/output	Port 95: I/O port
		Input	Timer input B: Input pin for timer 9
		Input	Interrupt request pin 8: Rising edge interrupt request pin 
P96 / TOA / TOB	1	Input/output	Port 96: I/O port
		Output	Timer output A: Output pin for timer 9
		Output	Timer output B: Output pin for timer 9
PA0 to PA2 / AN0 to AN2	3	Input	Port A0 to A2: Input-only port
		Input	Analog input 0 to 2: AD converter input pins
PA3 / AN3 / $\overline{\text{ADTRG}}$	1	Input	Port A3: Input-only port
		Input	Analog input 3: AD converter input pin
		Input	External start trigger

Table 2.2.1 Pin names and functions (4/4)

Pin Name	Number of Pins	Input/Output	Function
PA4 to PA7 / AN4 to AN7	4	Input	Port A4 to A7: Input-only port
		Input	Analog input 4 to 7: AD converter input pins
$\overline{\text{NMI}}$	1	Input	Non-maskable interrupt request pin: Interrupt request pin with programmable falling edge or both falling and rising edge 
CLK	1	Output	Clock output: Outputs external clock divided by 4. Pulled up during reset.
$\overline{\text{EA}}$	1	Input	External access: Connect to VCC.
AM8 / $\overline{16}$	1	Input	Address mode: External data bus width select pin Connect this pin to VCC. Data bus width at external access can be set by bus width/wait control register.
$\overline{\text{RESET}}$	1	Input	Reset: Initializes TMP95FW54A (with built-in pull-up resistor)
VREFH	1	Input	Reference voltage input pin for AD converter (high)
VREFL	1	Input	Reference voltage input pin for AD converter (low)
AVCC	1		Power supply pin for AD converter: Connect to power supply
AVSS	1		GND pin for AD converter: Connect to GND
X1 / X2	2	Input/output	Oscillator connecting pin
VCC	3		Power supply pin: Connect all VCC pins to power supply
VSS	5		GND pin: Connect all VSS pins to GND (0 V)

Note: Disconnect the pull-up resistors from pins other than $\overline{\text{RESET}}$ pin by software.
P30 is pulled-up during reset and input mode.
P57 and CLK pin are pulled-up only during reset.

3. Functional Description

This section shows the hardware configuration of the TMP95FW54A and explains how it operates.


This device is a version of the created by replacing the predecessor's internal mask ROM with a 128-Kbyte internal flash memory and expanding its internal RAM size to 4 Kbytes. The configuration and the functionality of this device are the same as those of the TMP95CU54A. For the functions of this device that are not described here, refer to the TMP95CU54A data sheet.

3.1 Outline of Operation Modes

There are single-chip and single-boot modes. Which mode is selected depends on the device's pin state after a reset.

- Single-chip mode: The device normally operates in this mode. After a reset, the device starts executing the internal flash memory program.
- Single-boot mode: This mode is used to rewrite the internal flash memory by serial transfer (UART). After a reset, the internal boot ROM starts up, executing a on-board rewrite program.

Table 3.1.1 Operation Mode Setup Table

Operation Mode	Mode Setup Input Pin		
	$\overline{\text{RESET}}$	$\overline{\text{BOOT}}$	$\overline{\text{EA}}$
Single-chip mode		1	1
Single-boot mode		0	1

3.2 Memory Map

The memory map of this device differs from that of the TMP95CU54A.

Figure 3.2.1 shows a memory map of the device in single-chip mode and its memory areas that can be accessed in each addressing mode of the CPU.

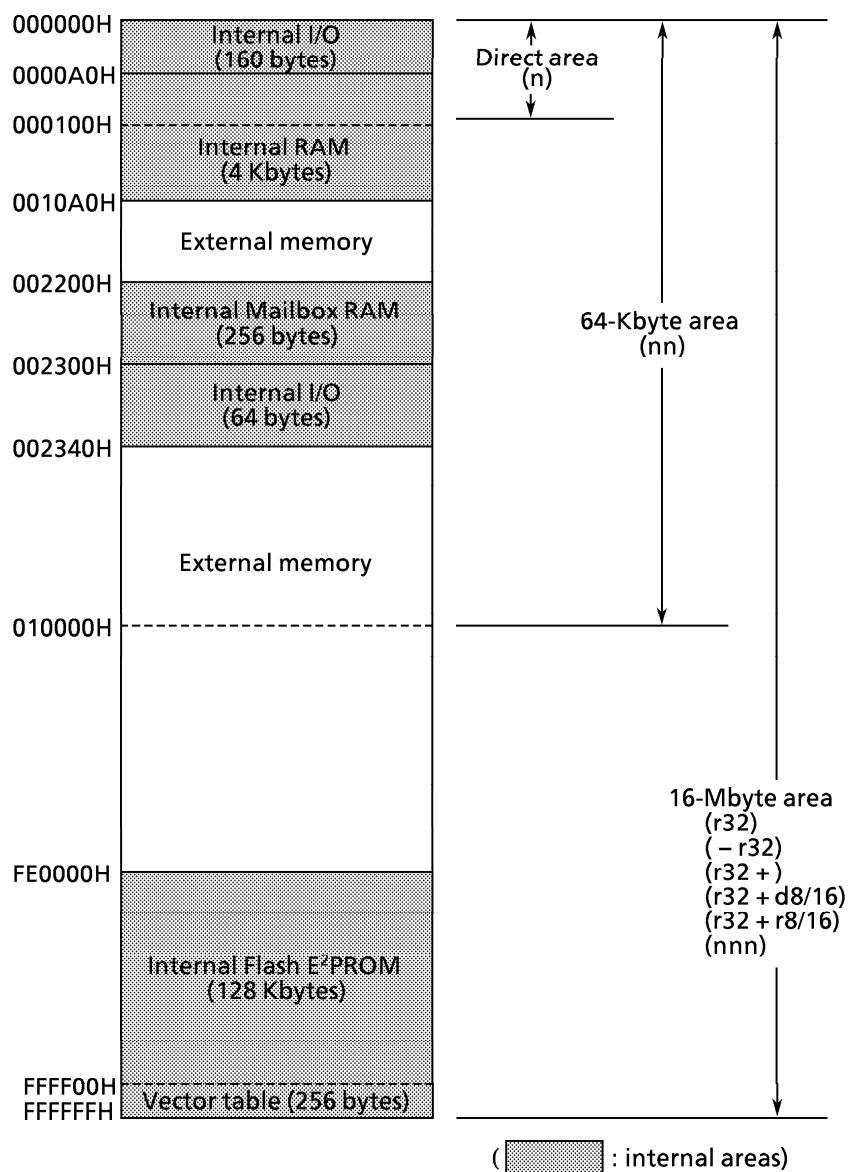


Figure 3.2.1 TMP95FW54A Memory Map (single-chip mode)

3.3 Flash Memory

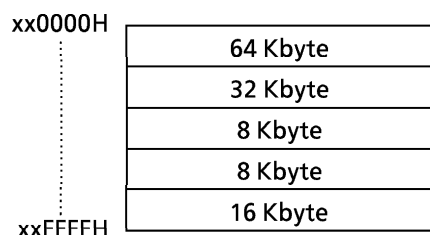
The TMP95FW54A contains an electrically erasable and programmable flash memory using a single 5 V power supply.

The standard JEDEC commands are used to electrically erase and program this flash memory. Once commands are entered, programming and erasure are automatically performed inside the chip. In addition, there are several methods for erasing the flash memory, so that it can be erased the entire chip collectively, one block at a time, or multiple blocks together.

Features:

- Program / erase power supply voltage
 $V_{CC} = 5\text{ V} \pm 10\%$
- Structure
128 K \times 8 bits /
64 K \times 16 bits (128 Kbytes)
- Functions
Automatic program
Automatic erase
Automatic block erase
Automatic multiblock erase
Data polling / toggle bit
- Block erase architecture
16 Kbytes \times 1 / 8 Kbytes \times 2 /
32 Kbytes \times 1 / 64 Kbytes \times 1
- Mode control
Based on standard JEDEC commands
- General-purpose flash memory type
Equivalent to 29F200T
* Some functions such as block protect are not supported, however.

Block structure:



xx: Depends on the microcomputer's operation mode.

Figure 3.3.1 Block Structure of the Flash Memory

Command Sequence: Flash memory access by the internal CPU
(Single-boot and user-boot modes)

Command Sequence	Bus Cycles	First Bus Write Cycle		Second Bus Write Cycle		Third Bus Write Cycle		Fourth Bus Read / Write Cycle		Fifth Bus Write Cycle		Sixth Bus Write Cycle	
		Address	Data	Address	Data	Address	Data	Address	Data	Address	Data	Address	Data
Read / reset	1	xXXXXH	F0H	—	—	—	—	—	—	—	—	—	—
Read / reset	3	xAAAAH	AAH	x5554H	55H	xAAAAH	F0H	RA	RD	—	—	—	—
Auto program	4	xAAAAH	AAH	x5554H	55H	xAAAAH	A0H	PA	PD	—	—	—	—
Auto chip erase	6	xAAAAH	AAH	x5554H	55H	xAAAAH	80H	xAAAAH	AAH	x5554H	55H	xAAAAH	10H
Auto block erase	6	xAAAAH	AAH	x5554H	55H	xAAAAH	80H	xAAAAH	AAH	x5554H	55H	BA	30H

The addresses viewed from the CPU side are shown in the table below.

Command Address	CPU Address: A23 to A0																
Address	A23 to A16	A15	A14	A13	A12	A11	A10	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0
xXXXXH	Flash memory address area	X	X	X	X	X	X	X	X	X	X	X	X	X	X	X	0
xAAAAH		1	0	1	0	1	0	1	0	1	0	1	0	1	0	1	0
x5554H		0	1	0	1	0	1	0	1	0	1	0	1	0	1	0	0

F0H, AAH, 55H, A0H, 80H, 10H, 30H: Command data. Written to DQ7 to DQ0.

RA: Read address

RD: Read data output

] Data is read out in units of bytes / words.

PA: Program address

PD: Program data input

] Data is written to every even address in units of words.

BA: Block address. Each individual block is selected by a combination of A17, A16, A15, A14, and A13.

*: The two reset commands each can reset the device to read mode.

Hardware Sequence Flag List: Flash memory access by the internal CPU

Status		DQ7	DQ6	DQ5	DQ3
Automatic operation under execution	Auto program	DQ7 inverted	Toggle	0	0
	Auto erase (during erase hold time)	0	Toggle	0	0
	Auto erase	0	Toggle	0	1
Time-out (automatic operation failed)	Auto program	DQ7 inverted	Toggle	1	1
	Auto erase	0	Toggle	1	1

Note: DQ8 to DQ15, DQ0 to DQ2 and DQ4 are “Don’t care.”

Block Erase Address Table: Flash memory access by the internal CPU

Block	Address in Single Chip Mode					Address Range		Size
	A17	A16	A15	A14	A13	Single Chip	Single Boot	
BA0	H	L	x	x	x	FE0000H-FFFFFFH	030000H-03FFFFH	64 Kbytes
BA1	H	H	L	x	x	FF0000H-FF7FFFH	040000H-047FFFH	32 Kbytes
BA2	H	H	H	L	L	FF8000H-FF9FFFH	048000H-049FFFH	8 Kbytes
BA3	H	H	H	L	H	FFA000H-FFBFFFH	04A000H-04BFFFH	8 Kbytes
BA4	H	H	H	H	x	FFC000H-FFFFFFH	04C000H-04FFFFH	16 Kbytes

Basic Operation: Flash memory access by the internal CPU

Broadly classified, this flash memory has two operation modes.

These are “Read Mode” in which memory data is read out and “Automatic Operation Mode” in which memory data are automatically erased / rewritten. Automatic operation mode can be entered by executing a command sequence in read mode. No memory data can be read out during automatic operation mode.

(1) Read

To read data from the flash memory, place it in read mode.

Immediately after power-on or when automatic operation has terminated normally, the flash memory goes to read mode. When automatic operation has terminated abnormally or you want read mode to be restored from the other mode, use the reset command that is described later.

(2) Command write

This flash memory uses JEDEC-compliant command control method provided for standard E²PROMs. Writing to the command register is accomplished by issuing a command sequence to the flash memory. The flash memory latches the entered address and data into the command register as it executes instructions.

To enter command data, use DQ0 to DQ7. Inputs to DQ8 to DQ15 are ignored.

If you want to cancel commands in the middle of a command sequence being entered, issue the reset command. Upon accepting the reset command, the flash memory resets the command register and enters read mode. Also, when an incorrect command sequence is entered, the flash memory resets the command register and enters read mode.

(3) Reset (reset command)

When automatic operation has terminated abnormally, the flash memory does not return to read mode. In this case, use the read / reset command to have the flash memory return to read mode.

Also, if you want to cancel a command in the middle while entering it, you can use the read / reset command. It clears the content of the command register.

(4) Auto program

Write to the flash memory is performed every even address in units of words. In Auto program operation, the program address and program data are latched every even addresses in units of words in the 4th bus write cycle of the command cycle. Upon latching the program data, the flash memory starts auto-programming. Once this operation begins, programming and program verification are automatically performed inside the chip. The status of Auto program operation can be confirmed by checking the hardware sequence flag.

During Auto program operation, command sequences you enter cannot be accepted.

In writing to the flash memory, the cells that contain data 1 can be turned to data 0, but the cells that contain data 0 cannot be turned to data 1. To change the data 0 cells to data 1, you need to perform an erase operation.

If Auto program fails, the flash memory is locked in that mode and does not return to read mode. This status can be confirmed by checking the hardware sequence flag. When in this state, the flash memory needs to be reset by the reset command. Since in this case writing to the address concerned has failed, the memory block that includes this address is faulty. Therefore, make sure this block will not be used.

(5) Auto chip erase

Auto chip erase begins from the 6th bus write cycle of the command cycle ended. Once Auto chip erase starts, all addresses of the flash memory are preprogrammed with data 0, with the contents then erased and verified for erasure. All this operation is performed automatically inside the chip. The status of Auto chip erase operation can be confirmed by checking the hardware sequence flag.

During Auto chip erase operation, command sequences you enter cannot be accepted.

If Auto chip erase fails, the flash memory is locked in that mode and does not return to read mode. This status can be confirmed by checking the hardware sequence flag. Reset the flash memory by using the reset command. The block in which the failure occurred cannot be detected. Therefore, you need to stop using the device or locate the faulty block by executing block erase. Make sure the faulty block thus found will not be used.

(6) Auto block erase and Auto multiblock erase

Auto block erase begins from the 6th bus write cycle of the command cycle ended after an elapse of the erase hold time. Once Auto block erase starts, all addresses of a selected block are preprogrammed with data "0," with the contents then erased and verified for erasure. All this operation is performed automatically inside the chip. To erase multiple blocks, repeat the 6th bus write cycle and while so doing, enter each block address and the Auto block erase command within the erase hold time. If any other command sequence than Auto block erase is entered during the erase hold time, the flash memory is reset and placed in read mode. The erase hold time is 50 μ s, and count starts each time the 6th bus write cycle has ended. The status of Auto block erase operation can be confirmed by checking the hardware sequence flag.

During Auto block erase, command sequences you enter cannot be accepted.

If Auto block erase fails, the flash memory is locked in that mode and does not return to read mode. This status can be confirmed by checking the hardware sequence flag. Reset the flash memory by using the reset command. If multiple blocks have been selected, the block in which the failure occurred cannot be detected. Therefore, you need to stop using the device or locate the faulty block by executing block erase for each block individually. Make sure the faulty block thus found will not be used.

(7) Hardware sequence flags

The hardware sequence flag allows you to confirm the status of the flash memory automatic operation being executed. During automatic operation, data can read from memory at the same timing as in read mode.

When the flash memory finishes automatic operation, it automatically returns to read mode.

The operating status when automatic operation is being executed can be confirmed by checking the hardware sequence flag, and the status after automatic operation is completed can be confirmed by checking whether the data read from memory matches its cell data.

1) DQ7 (DATA polling)

The DATA polling function allows you to confirm the status of the flash memory automatic operation. The DATA polling output begins from the last bus write cycle of the automatic operation command sequence ended. During Auto program operation, the data that has been written to DQ7 is output after being inverted; after the operation is completed, the cell data in DQ7 is output. By reading data out of DQ7, you can identify the operating status. During Auto erase operation, data 0 is output from DQ7; after the operation is completed, data 1 (cell data) is output. If the automatic operation resulted in failure, DQ7 continues outputting the same data that was written to it during automatic operation.

The flash memory frees address latch upon completion of operation, so that when you read data from memory you must enter the address to which data has been written or any block address being erased.

2) DQ6 (toggle bit)

In addition to DATA polling, you can use a toggle bit output function to recognize the status of automatic operation.

Toggle output begins from the last bus write cycle of the automatic operation command sequence ended. This toggle is output to DQ6, with data 1 and 0 output alternately for each read cycle performed. When the automatic operation is completed, DQ6 stops outputting the toggle and instead, outputs its cell data. If the automatic operation has failed, DQ6 continues outputting the toggle.

3) DQ5 (internal timer overtime)

When performing automatic operation normally, the flash memory outputs a 0 to DQ5. If the automatic operation exceeds the flash memory's internally predetermined time, the DQ5 output changes to a 1. This means that the automatic operation did not terminate normally, and that the flash memory probably is faulty.

However, when data 1 is written to the data 0 cell, DQ5 outputs a 1, providing misleading information that the flash memory is faulty. (The flash memory is designed in such a way that although the data 1 cells can be turned to data 0 in program mode, the data 0 cells cannot be turned to data 1.) In the above case, DQ5 is not showing that the flash memory is faulty, but that the method of command usage is incorrect.

If the automatic operation did not terminate normally, the flash memory is locked and does not return to read mode. Therefore, reset the flash memory using the reset command.

4) DQ3 (block erase timer)

Auto block erase begins from the 6th bus write cycle of the command cycle ended after an elapse of the erase hold time (80 μ s). The flash memory outputs a 0 to DQ3 when in the erase hold time and a 1 when it starts erasing. When you want to add a block to be erased, enter it during the block erase hold time. Every time you enter the erase command for each block, the flash memory resets the block erase hold time and starts counting over again. If the automatic operation resulted in failure, DQ3 outputs a 1.

5) RY / $\overline{\text{BY}}$ (ready / busy)

* This function cannot be used because the flash memory is not connected to the internal CPU.

(8) Flash memory rewrite by the internal CPU

Flash memory rewrite by the internal CPU is accomplished by using the command sequence and hardware sequence flags described above. However, since the built-in flash memory does not read data from its memory cells during automatic operation mode, the rewrite program must be executed external to the flash memory.

There are two methods for flash memory rewrite by the internal CPU. One method uses the single-boot mode prepared in advance; the other method runs the user's original protocol in single-chip mode (user boot).

1) Single boot

In this method, the microcomputer is started in single-boot mode and the flash memory is rewritten using the internal boot ROM program. In this mode, the internal boot ROM is mapped into an area that includes the interrupt vector table, and the boot ROM program is executed in that area. The flash memory is mapped into another address space separately from the boot ROM area. The boot ROM program mainly performs two operations: taking in the rewrite data by serial transfer and rewriting the flash memory. Single boot needs to be performed while interrupts are disabled. Make sure nonmaskable interrupts (e.g., NMI) also are disabled before performing single boot.

For details, refer to Section 3.4, "Single Boot Mode."

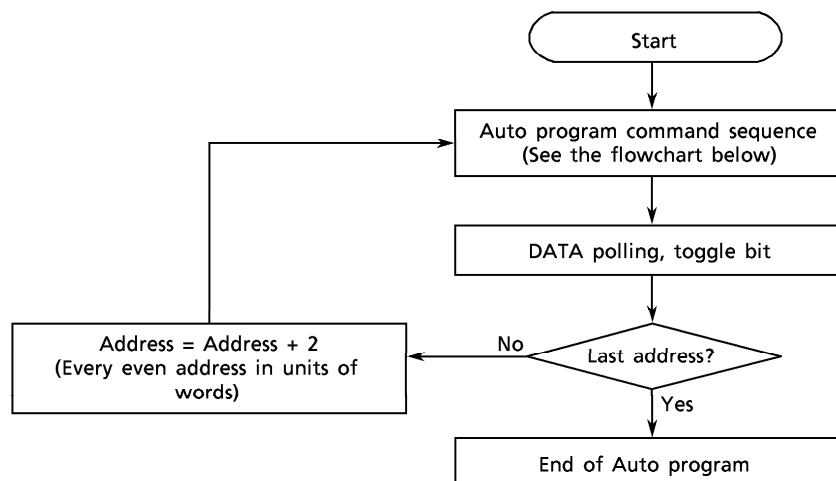
2) User boot

This method runs the user's original flash memory rewrite program. Execute the program in single-chip mode (regular operation mode). In this mode too, the flash memory rewrite program must be executed in another address space separately from that of the flash memory. As in the case of single boot, nonmaskable and all other interrupts must be disabled before performing user boot.

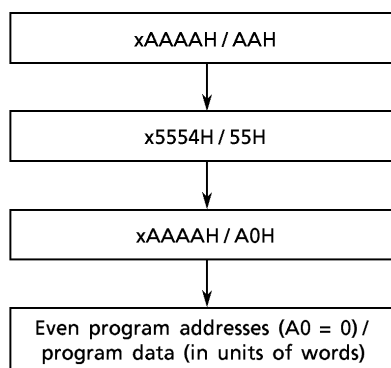
The flash memory rewrite program including routines for taking in the rewrite data and rewriting the flash memory needs to be prepared in advance. When in the main program, switch from regular operation to the flash memory rewrite operation, then execute the flash memory rewrite program you've prepared after expanding it into somewhere outside the flash memory area. For example, you can execute the flash memory rewrite program after expanding it from flash memory into internal RAM or after preparing it in external memory.

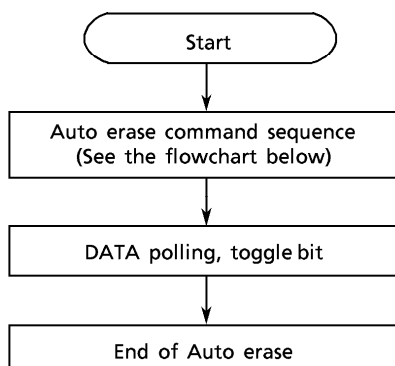
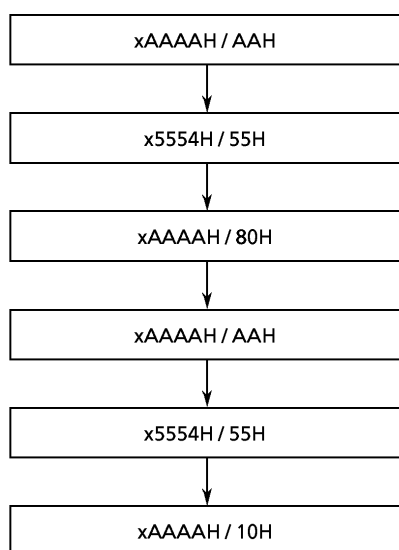
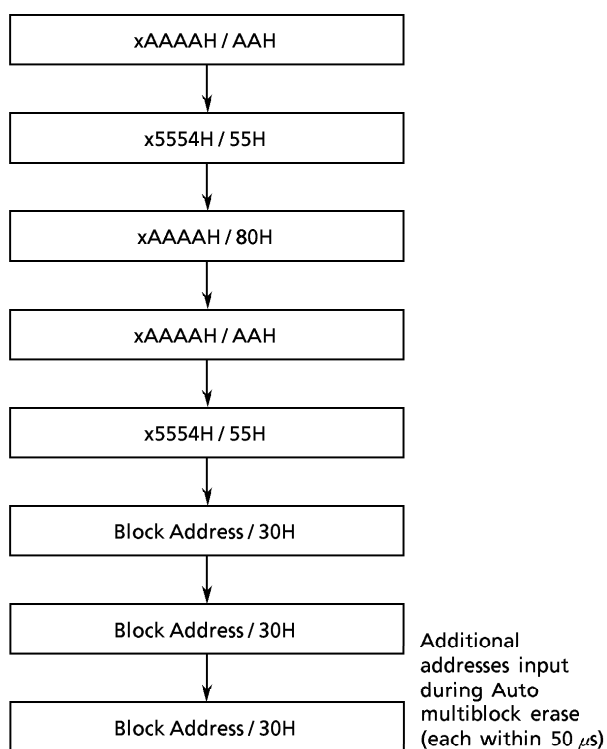
Flowchart: Flash memory access by the internal CPU

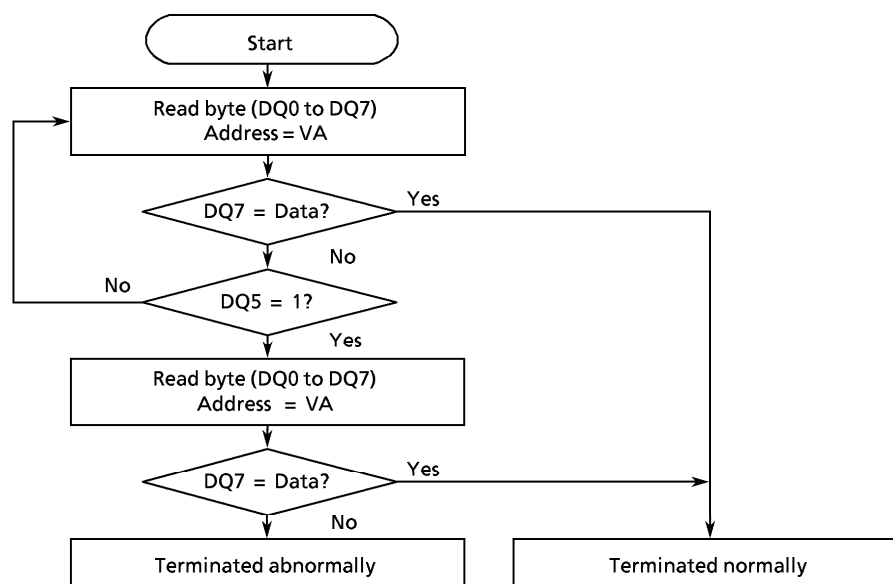
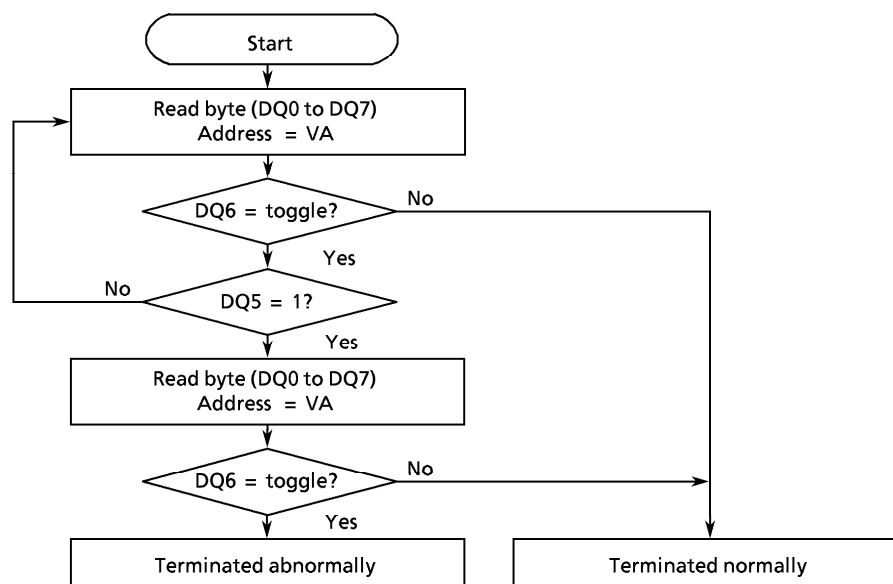
Auto program



Auto program command sequence (addresses / commands)



Auto eraseAuto chip erase command sequence
(addresses / commands)Auto block / multiblock erase command sequence
(addresses / commands)

DQ7 DATA pollingDQ6 toggle bit

VA: During Auto program, it denotes the address being written to.
 During Auto chip erase, it denotes an arbitrary flash memory address.
 During Auto block erase, it denotes a selected block address.

3.4 Single Boot Mode

(1) Outline

The TMP95FW54A has single-boot mode available as an on-board programming operation mode. When in single-boot mode, the boot ROM is mapped into memory space. This boot ROM is a mask ROM that contains a program to rewrite the flash memory on-board.

On-board programming is accomplished by first connecting the device's SIO (channel 1) and programming tool (controller) and then sending commands from the controller to the target board.

The boot program included in the boot ROM also has the function of a loader, so it can transfer program data from an external source into the device's internal RAM.

Figure 3.4.1 shows an example of how to connect the programming controller and the target board.

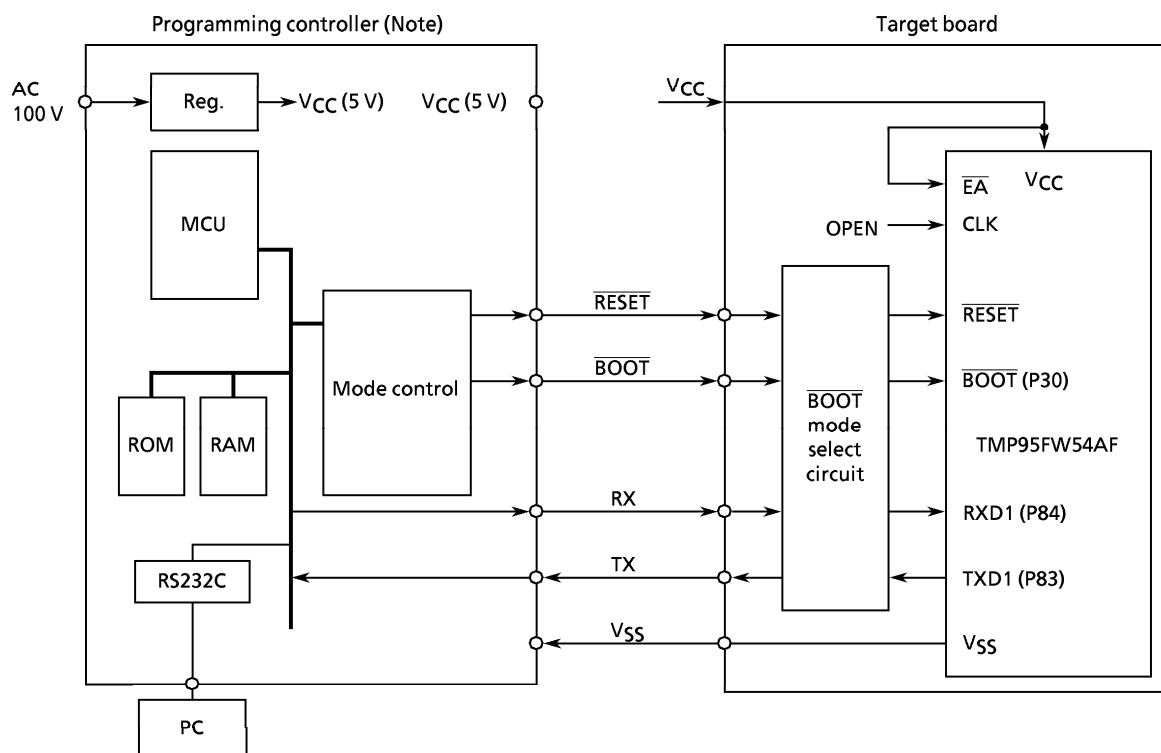


Figure 3.4.1 Example for Connecting Units for On-board Programming

Note: One of the programming controllers supported for the TMP95FW54A is the AF200 (Advanced On-board Flash Microcomputer Programmer) from Yokogawa Digital Computer Co. For details, refer to the manual included with the AF200.

Where to contact: **North America**

Yokogawa Digital Computer America

Tel: 408-244-1932

Fax: 408-244-1881

European Area

Ashling Microsystems Limited

Tel: 353-61-334466

Fax: 353-61-334477

Tel: 44-1256-811998

Fax: 44-1256-811761

Korea

KM DATA INC.

Tel: 82-2-785-3929

Fax: 82-2-785-3117

(2) Mode settings

To execute on-board programming, start the TMP95FW54A in single-boot mode. Settings necessary to start up in single-boot mode are shown below.

$$\begin{array}{rcl} \overline{\text{EA}} & = & \text{H} \\ \overline{\text{BOOT}} (\text{P30}) & = & \text{L} \\ \overline{\text{RESET}} & = & \text{⌈} \end{array}$$

After setting the $\overline{\text{EA}}$ and $\overline{\text{BOOT}}$ pins each to the above conditions, drive the signal input to the $\overline{\text{RESET}}$ pin high. The TMP95FW54A starts up in single-boot mode.

(3) Memory map

Figure 3.4.2 compares memory maps in single-chip and single-boot modes. When in single boot mode, the internal flash memory is mapped into addresses 30000H through 4FFFFH, as shown here. You'll also find that the boot ROM (MROM) is mapped into addresses FFF800H through FFFFFH.

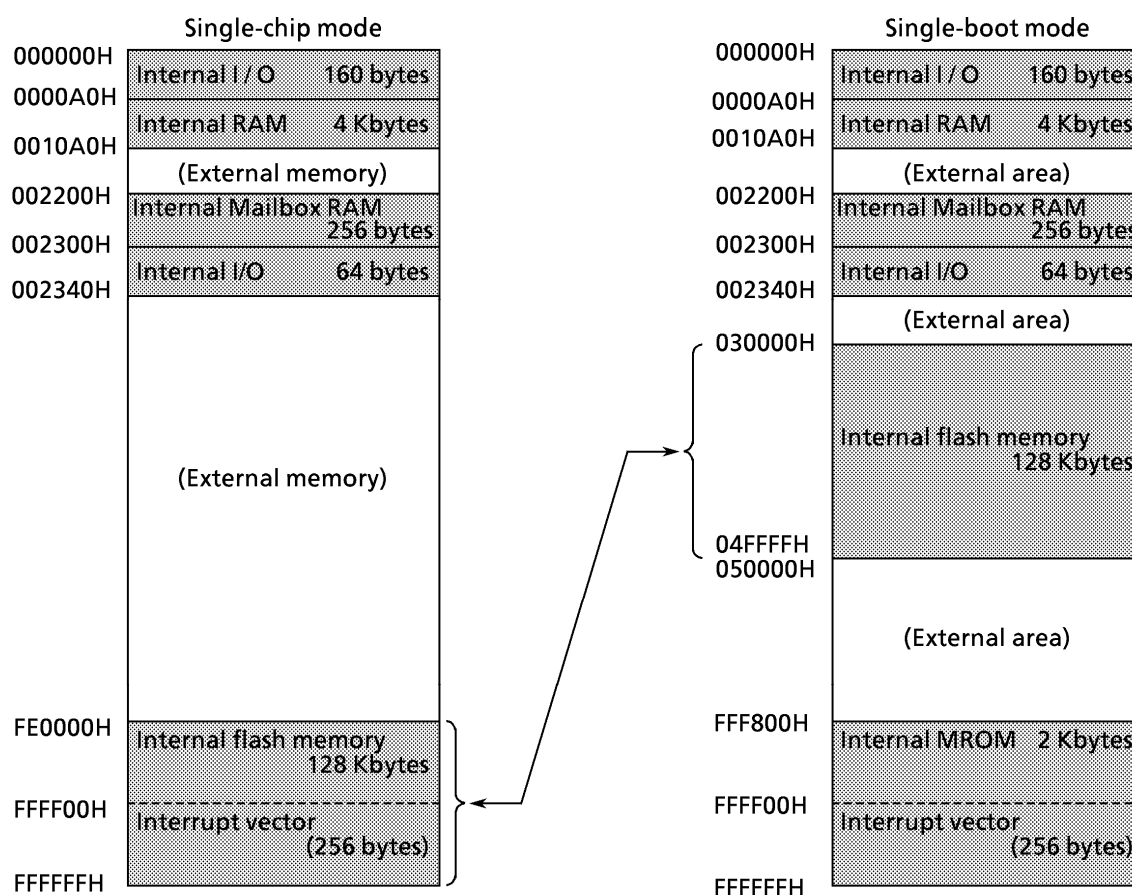


Figure 3.4.2 Comparison of Memory Maps

(4) Interface specifications

The following shows the SIO communication format used in single-boot mode.

Before on-board programming can be executed, the communication format on the programming controller side must also be set up in the same way as for the TMP95FW54A.

Note that although the default baud rate is 9,375 bps (at $f_c = 24$ MHz), it can be changed to other values as shown in Table 3.4.1.

Communication channel: SIO channel 1

Serial transfer mode: UART (asynchronous communication) mode, full-duplex communication

Data length: 8 bits

Parity bit: None

Stop bit: 1 bit

Baud rate (default): 9,375 bps (at $f_c = 24$ MHz)

(5) Data transfer format

Tables 3.4.1 through 3.4.6 show baud rate modification data, operation commands, and data transfer format in each operation mode, respectively.

Also refer to the description of boot program operation in the latter pages of this manual as you read these tables.

Table 3.4.1 Baud Rate Modification Data (at $f_c = 24$ MHz)

Baud Rate Modification Data	04H	05H	06H	07H	0AH	18H	28H
Baud Rate (bps)	75000	62500	53571	37500	31250	18750	9375

Note: The baud rates currently supported by the AF200 are 9600, 19200, 31250, and 62500 bps only.

Table 3.4.2 Operation Command Data

Operation Command Data	Operation Mode
30H	Flash memory rewrite
60H	RAM loader
90H	Flash memory SUM

Table 3.4.3 Boot Program Transfer Format (at $f_c = 24$ MHz) (For Flash Memory Rewrite)

	Number of Bytes Transferred	Transfer Data from Controller to TMP95FW54A	Baud Rate	Transfer Data from TMP95FW54A to Controller
BOOT ROM	1st byte	Matching data (5AH)	9375 bps	– (Baud rate auto set)
	2nd byte	–	9375 bps	OK: Echoback data (5AH) NG: Nothing transmitted
	3rd byte	Baud rate modification data	9375 bps	–
	4th byte	(See Table 3.4.1) –	9375 bps	OK: Echoback data NG: A1H \times 3, A2H \times 3, A3H \times 3
	5th byte	Operation command data (30H)	Changed new baud rate	–
	6th byte	–	Changed new baud rate	OK: Echoback data (30H) NG: A1H \times 3, A2H \times 3, A3H \times 3, 63H \times 3
	7th byte	–	Changed new baud rate	OK: C1H NG: 64H \times 3
	8th byte : n'th – 2 byte	Extended Intel Hex format (binary)	Changed new baud rate	–
	n'th – 1 byte	–	Changed new baud rate	OK: SUM (High) NG: Nothing transmitted
	n'th byte	–	Changed new baud rate	OK: SUM (Low) NG: Nothing transmitted
	n'th + 1 byte	(Wait for the next operation command data)	Changed new baud rate	–

*1: “xxH \times 3” denotes that operation stops after sending 3 bytes of xxH.

*2: Refer to “Notes on Extended Intel Hex Format (Binary)” in the latter page of this manual.

*3: Refer to “Notes on SUM” in the latter page of this manual.

Table 3.4.4 Boot Program Transfer Format (at $f_c = 24$ MHz) (For RAM Loader)

	Number of Bytes Transferred	Transfer Data from Controller to TMP95FW54A	Baud Rate	Transfer Data from TMP95FW54A to Controller
BOOT ROM	1st byte	Matching data (5AH)	9375 bps	– (Baud rate auto set)
	2nd byte	–	9375 bps	OK: Echoback data (5AH) NG: Nothing transmitted
	3rd byte	Baud rate modification data (See Table 3.4.1)	9375 bps	–
	4th byte		9375 bps	OK: Echoback data NG: A1H \times 3, A2H \times 3, A3H \times 3, 62H \times 3
	5th byte	Operation command data (60H)	Changed new baud rate	–
	6th byte		Changed new baud rate	OK: Echoback data (60H) NG: A1H \times 3, A2H \times 3, A3H \times 3, 63H \times 3
	7th byte	Address 23-16* ² in which to store Password count	Changed new baud rate	–
	8th byte		Changed new baud rate	OK: Nothing transmitted NG: A1H \times 3, A2H \times 3, A3H \times 3
	9th byte	Address 15-08* ² in which to store Password count	Changed new baud rate	–
	10th byte		Changed new baud rate	OK: Nothing transmitted NG: A1H \times 3, A2H \times 3, A3H \times 3
	11th byte	Address 07-00* ² in which to store Password count	Changed new baud rate	–
	12th byte		Changed new baud rate	OK: Nothing transmitted NG: A1H \times 3, A2H \times 3, A3H \times 3
	13th byte	Address 23-16* ² at which to start Password comparison	Changed new baud rate	–
	14th byte		Changed new baud rate	OK: Nothing transmitted NG: A1H \times 3, A2H \times 3, A3H \times 3
	15th byte	Address 15-08* ² at which to start Password comparison	Changed new baud rate	–
	16th byte		Changed new baud rate	OK: Nothing transmitted NG: A1H \times 3, A2H \times 3, A3H \times 3
	17th byte	Address 07-00* ² at which to start Password comparison	Changed new baud rate	–
	18th byte		Changed new baud rate	OK: Nothing transmitted NG: A1H \times 3, A2H \times 3, A3H \times 3
	19th byte	Password string	Changed new baud rate	–
	:		Changed new baud rate	OK: Nothing transmitted
	m'th byte	–	Changed new baud rate	NG: A1H \times 3, A2H \times 3, A3H \times 3
	m'th + 1 byte	Extended Intel Hex format (Binary)		–
	:			
	n'th – 2 byte			
	n'th – 1 byte	–	Changed new baud rate	OK: SUM (High) NG: Nothing transmitted
	n'th byte	–	Changed new baud rate	OK: SUM (Low) NG: Nothing transmitted
RAM	–	Jump to the user program's start address		

*1: “xxH \times 3” denotes that operation stops after sending 3 bytes of xxH.

*2: Refer to “Notes on Password” in the latter page of this manual.

*3: Refer to “Notes on Extended Intel Hex Format (Binary)” in the latter page of this manual.

*4: Refer to “Notes on SUM” in the latter page of this manual.

Table 3.4.5 Boot Program Transfer Format (at $f_c = 24$ MHz) (For Flash Memory SUM)

	Number of Bytes Transferred	Transfer Data from Controller to TMP95FW54A	Baud Rate	Transfer Data from TMP95FW54A to Controller
BOOT ROM	1st byte	Matching data (5AH)	9375 bps	– (Baud rate auto set)
	2nd byte	–	9375 bps	OK: Echoback data (5AH) NG: Nothing transmitted
	3rd byte	Baud rate modification data (See Table 3.4.1)	9375 bps	–
	4th byte		9375 bps	OK: Echoback data NG: A1H \times 3, A2H \times 3, A3H \times 3, 62H \times 3
	5th byte	Operation command data (90H)	Changed new baud rate	–
	6th byte		Changed new baud rate	OK: Echoback data (90H) NG: A1H \times 3, A2H \times 3, A3H \times 3, 63H \times 3
	7th byte	–	Changed new baud rate	OK: SUM (High) NG: –
	8th byte	–	Changed new baud rate	OK: SUM (Low) NG: –
	9th byte	(Wait for the next operation command data)	Changed new baud rate	–

*1: “xxH \times 3” denotes that operation stops after sending 3 bytes of xxH.

*2: Refer to “Notes on SUM.”

(6) Description of boot program operation

When you start the TMP95FW54A in single-boot mode, the boot program starts up. The boot program provides the functions described below.

For details about these functions, refer to ① Flash memory rewrite program through ③ Flash memory SUM command in the pages that follow.

1. Flash memory rewrite

The flash memory is erased the entire chip (128 Kbytes) collectively. Then data are written to the specified flash memory addresses. The controller should send the write data in the Extended Intel Hex format (binary).

If no errors are encountered till the end record, the SUM of 128 Kbytes of flash memory is calculated and the result is returned to the controller.

2. RAM loader

The RAM loader transfers the data into the internal RAM that has been sent from the controller in Extended Intel Hex format. When the transfer has terminated normally, the RAM loader calculates the SUM and sends the result to the controller before it starts executing the user program. The execution start address is the first address received. This RAM loader function provides the user's own way to control on-board programming.

To execute on-board programming in the user program, you need to issue the flash memory command sequence described in the preceding section of this manual. (Must be matched to the flash memory addresses in single-boot mode.)

The RAM loader command checks the result of password collation prior to program execution. If the passwords did not match, the program is not executed.

3. Flash memory SUM

The SUM of 128 Kbytes of flash memory is calculated and the result is returned to the controller.

The boot program does not support the operation commands to read data from the flash memory. Instead, it has this SUM command to use. By reading the SUM, it is possible to manage Revisions of application programs.

① Flash memory rewrite command (Table 3.4.3)

1. The receive data in the first byte is the matching data. When the boot program starts in single-boot mode, it goes to a state in which it waits for the matching data to receive. Upon receiving the matching data, it automatically adjusts the serial channels' initial baud rate to 9,375 bps.
The matching data is 5AH.
2. The 2nd byte is used to echo back 5AH to the controller upon completion of the automatic baud rate setting in the first byte. If the device fails in automatic baud rate setting, it goes to an idle state.
3. The receive data in the 3rd byte is the baud rate modification data. The seven kinds of baud rate modification data shown in Table 3.4.1 are available. Even when you do not change the baud rate, be sure to send the initial baud rate data (28h: 9,375 bps at $f_c = 24$ MHz).
Baud rate modification becomes effective after the echoback transmission is completed.
4. The 4th byte is used to echo back the received data to the controller when the data received in the third byte is one of the baud rate modification data corresponding to the device's operating frequency. Then the baud rate is changed. If the received baud rate data does not correspond to the device's operating frequency, the device goes to an idle state after sending 3 bytes of baud rate modification error code (62H).

5. The receive data in the 5th byte is the command data (30H) to rewrite the flash memory.
6. The 6th byte is used to echo back the received data (in this case, 30H) to the controller when the data received in the 5th byte is one of the operation command data in Table 3.4.2. And the flash memory rewrite routine is called. If the received data is none of the operation command data, the device goes to an idle state after sending 3 bytes of operation command error code (63H).
7. The transmit data in the 7th byte indicates whether collective erase (128 Kbytes) has terminated normally. When collective erase (128 Kbytes) has terminated normally, the device returns collective erase terminated normally code (C1H) to the controller.
If an erase error occurs, the device goes to an idle state after returning three bytes of erase error code (64H) to the controller.
The controller should send the next data to the device after receiving the collective erase terminated normally code (C1H).
8. The receive data in the 8th byte through n'th – 2 byte are received as binary data in Extended Intel Hex format. No received data are echoed back to the controller.
The flash memory rewrite routine ignores the received data until it receives the start mark (3AH for “:”) in Extended Intel Hex format. Nor does it send error code to the controller. After receiving the start mark, the routine receives a range of data from data length to checksum and writes the received write data to the specified flash memory addresses successively. Since bits 23 to 16 of the address pointer during write are by default 00H, the first record type must always be an extended record.
After receiving one record of data from start mark to checksum, the routine goes to a start mark waiting state again.
If a write error, receive error, or Extended Intel Hex format error occurs, the device goes to an idle state without returning error code to the controller.
Because the flash memory rewrite routine executes a SUM calculation routine upon detecting the end record, the controller should be placed in a SUM waiting state after sending the end record to the device.
9. The n'th – 1 and the n'th bytes are the SUM value that is sent to the controller in order of the upper byte and the lower byte. For details on how to calculate the SUM, refer to “Notes on SUM” in the latter page of this manual. The SUM calculation is performed only when no write error, receive error, or Extended Intel Hex format error has been encountered after detecting the end record. The time required to calculate the SUM of the 128 Kbytes of flash memory area is approximately 400 ms at $f_c = 20$ MHz. After SUM calculation, the device sends the SUM data to the controller. The controller should determine whether writing to the flash memory has terminated normally depending on whether the SUM value is received after sending the end record to the device.
10. The receive data in the n'th + 1 byte, if rewriting terminated normally, places the device in a state waiting for the next operation command data.

② RAM loader command (Table 3.4.4)

1. The transmit / receive data in the 1st through the 4th bytes are the same as in the case of flash memory rewrite commands.
2. The receive data in the 5th byte is the RAM loader command data (60H).
3. The 6th byte is used to echo back the received data (in this case, 60H) to the controller when the data received in the 5th byte is one of the operation command data in Table 3.4.2. Then the RAM loader routine is called. If the received data is none of the operation command data, the device goes to an idle state after returning three bytes of operation command error code (63H) to the controller.
4. The receive data in the 7th byte is the data for bits 23 to 16 of the address in which the password count is stored. Three bytes of password count storage address are required. The data indicated by this address is the password count. Note that if the password count is equal to or less than 8, the command is canceled.
5. Nothing is sent in the 8th byte to the controller when the data received in the 7th byte has no error. If a receive error is encountered, the device goes to an idle state after returning three bytes of relevant error code to the controller.
6. The 9th through the 12th bytes respectively are bits 15 to 8 and bits 7 to 0 of the password count storage address and are the data used when a receive error is encountered to return error code to the controller. For these operations, refer to paragraphs 4 and 5 above.
7. The receive data in the 13th byte are bits 23 to 16 of the address at which the password comparison is started. Three bytes of password comparison start address are required. Passwords are compared beginning with this address.
8. Nothing is sent in the 14th byte to the controller when the data received in the 13th byte has no error. If a receive error is encountered, the device goes to an idle state after returning three bytes of relevant error code to the controller.
9. The 15th through the 18th bytes respectively are bits 15 to 8 and bits 7 to 0 of the password comparison start address and are the data returned to the controller. For these operations, refer to paragraphs 7 and 8 above.
10. The 19th through the m'th bytes are the password data. The number of passwords or the password count is the data (N) indicated by the password count storage address. The password data are compared for N entries beginning with the password comparison start address. The controller should send N bytes of password data to the device. If the passwords do not match, the device goes to an idle state without returning error code to the controller.

11. The receive data in the m'th + 1 through the n'th - 2 bytes are received as binary data in Extended Intel Hex format. No received data are echoed back to the controller.
The RAM loader routine ignores the received data until it receives the start mark (3AH for ":") in Extended Intel Hex format. Nor does it send error code to the controller. After receiving the start mark, the routine receives a range of data from data length to checksum. The received write data are successively written to the specified flash memory addresses. Since bits 23 to 16 of the address pointer during write are by default 00H, the first record type does not always have to be an extended record.
After receiving one record of data from start mark to checksum, the routine goes to a start mark waiting state again.
If a receive error or Extended Intel Hex format error occurs, the device goes to an idle state without returning nothing to the controller.
Because the RAM loader routine executes a SUM calculation routine upon detecting the end record, the controller should be placed in a SUM waiting state after sending the end record to the device.
12. The n'th - 1 and the n'th bytes are the SUM value that is sent to the controller in order of the upper byte and the lower byte. For details on how to calculate the SUM, refer to "Notes on SUM" in the latter page of this manual. The SUM calculation is performed only when no receive error or Extended Intel Hex format error has been encountered after detecting the end record. The time required to calculate the SUM is approximately proportional to the number of data written to RAM. The time required to calculate the SUM of a 4 Kbytes of RAM area, for example, is approximately 6 ms at $f_c = 20$ MHz. After SUM calculation, the device sends the SUM data to the controller. The controller should determine whether writing to RAM has terminated normally depending on whether the SUM value is received after sending the end record to the device.
13. The boot program jumps to the first address that is received as data in Extended Intel Hex format after sending the SUM to the controller.

③ Flash memory SUM command (Table 3.4.5)

1. The transmit / receive data in the 1st through the 4th bytes are the same as in the case of flash memory rewrite commands.
2. The receive data in the 5th byte is the flash memory SUM command data (90H).
3. The 6th byte is used to echo back the received data (in this case, 90H) to the controller when the data received in the 5th byte is one of the operation command data in Table 3.4.2. Then the flash memory SUM processing routine is called. If the received data is none of the operation command data, the device goes to an idle state after returning three bytes of operation command error code (63H) to the controller.
4. The 7th and the 8th bytes are the SUM value that is sent to the controller in order of the upper byte and the lower byte. For details on how to calculate the SUM, refer to "Notes on SUM" in the latter page of this manual.
5. The receive data in the 9th byte places the device in a state waiting for the next operation command data.

④ Boot program transmit data

The boot program sends the processing status to the controller using various code. The transmit data (processing code) are listed in the table below.

Table 3.4.6 Boot Program Transmit Data

Transmit Data	Meaning of Transmit Data
C1H	Collective erase of flash memory chip terminated normally.
62H, 62H, 62H	Baud rate modification error occurred.
63H, 63H, 63H	Operation command error occurred.
64H, 64H, 64H	Flash memory erase error occurred.
A1H, A1H, A1H	Framing error in received data occurred.
A2H, A2H, A2H	Parity error in received data occurred.
A3H, A3H, A3H	Overrun error in received data occurred.

*1: When this receive error occurs when receiving data in Extended Intel Hex format, the device does not send the receive error code to the controller.

⑤ Notes on SUM

1. Calculation method

SUM consists of byte + byte.....+ byte, the sum of which is returned in word as the result. Namely, data is read out in byte and sum of which is calculated, with the result returned in word.

Example:

A1H
B2H
C3H
D4H

If the data to be calculated consists of the four bytes shown to the left, SUM of the data is

$$A1H + B2H + C3H + D4H = 02EAH$$

$$\therefore \text{SUM (HIGH)} = 02H$$

$$\text{SUM (LOW)} = EAH$$

The SUM returned when executing the flash memory rewrite command, RAM loader command, or flash memory SUM command is calculated in the manner shown above.

2. Calculation data

The data from which SUM is calculated are listed in Table 3.4.7 below.

Table 3.4.7 SUM Calculation Data

Operation Mode	Calculation Data	Remarks
Flash memory rewrite command	Data in the entire area (128 Kbytes) of flash memory	The received flash memory or RAM write data is not the only data to be calculated for SUM. Even when the received addresses are noncontiguous and there are some unwritten areas, data in the entire memory area is calculated.
RAM loader command	Data written in an area ranging from the first address received to the last address received	
Flash memory SUM command	Data in the entire area (128 Kbytes) of flash memory	—

⑥ Notes on Extended Intel Hex Format (binary)

1. For the flash memory rewrite command, always make sure the first record type is an extended record. This is because the internal flash memory of the TMP95FW54A is located in a memory space starting from address 30000H, so that bits 23 to 16 of the address pointer when writing to the flash memory are, by default, 00H.
2. For the RAM loader command, the first record type does not always have to be an extended record. This is because bits 23 to 16 of the address pointer when writing to the flash memory are, by default, 00H.
3. After receiving the checksum of a record, the device waits for the start mark (3AH for “:”) of the next record. Therefore, the device ignores all data received between records during that time unless the data is 3AH.
4. Make sure that once the controller program has finished sending the checksum of the end record, it does not send anything and waits for two bytes of data to be received (upper and lower bytes of SUM). This is because after receiving the checksum of the end record, the boot program calculates the SUM and returns the calculated SUM in two bytes to the controller.
5. If a write error (for only the flash memory rewrite command), receive error, or Extended Intel Hex format error occurs, the device goes to an idle state without returning error code to the controller. In the following cases, an Extended Intel Hex format error is assumed:
 - When TYPE is not 00H, 01H, or 02H
 - When a checksum error occurred
 - When the data length of an extended record (TYPE = 02H) is not 02H
 - When the address of an extended record (TYPE = 02H) is not 0000H
 - When the data in the 2nd byte of an extended record (TYPE = 02H) is not 00H
 - When the data length of the end record (TYPE = 01H) is not 00H
 - When the address of the end record (TYPE = 01H) is not 0000H

Example: When writing to an area from address 3FFF8H to address 4002FH, the transfer format should be like the one shown in Table 3.4.8.

Table 3.4.8 Example of Transfer Format for Flash Memory Rewrite Command

Direction of Data	Meaning of Data Extended Intel Hex Format (n'th – 2 byte in item 8 of Table 3.4.3)	Data
Controller to TMP95FW54A	Extended record	: 02 0000 02 3000 <u>CC</u> <u>zz</u>
Controller to TMP95FW54A	Data record (data length: 08H)	: 08 FFF8 00 xxxxxx <u>CS</u> <u>zz</u>
Controller to TMP95FW54A	Extended record	: 02 0000 02 4000 <u>BC</u> <u>zz</u>
Controller to TMP95FW54A	Data record (data length: 30H)	: 30 0000 00 yyyyyyyy <u>CS</u> <u>zz</u>
Controller to TMP95FW54A	End record	: 00 0000 01 FF <u>ww</u>
TMP95FW54A to controller	SUM (upper byte) (n'th – 1 byte in Table 3.4.3)	SUM (upper byte)
TMP95FW54A to controller	SUM (lower byte) (n'th byte in Table 3.4.3)	SUM (lower byte)
Controller to TMP95FW54A	Operation command (n'th + 1 byte in Table 3.4.3)	Next operation command data

Note: The colon : denotes the start mark (3AH).
 xx, yy denote the data written to flash memory.
 CS, CC, BC, FF denote the checksum data.
zz denotes the data that can be sent by the controller without causing a problem.
ww denotes the data that cannot be sent by the controller.

⑦ Notes on Passwords

The area in which passwords can be specified is located at addresses 32000H to 4DFFFH. Figure 3.4.3 schematically shows the password area.

1. Password count storage address (PNSA)

The content of the address specified by PNSA is the password count (N). In the following cases, a password error is assumed:

- PNSA < address 32000H
- Address 4DFFFH < PNSA
- N < 8

2. Password comparison start address (PCSA)

The passwords are compared beginning with the address specified by PCSA. The specified password area is from PCSA to PCSA + N. In the following cases, a password error is assumed:

- PCSA < address 32000H
- Address 4DFFFH < PCSA + N - 1
- When the specified password area contains three or more consecutive bytes of the same data. However, if all data in the vector part (4FF00H to 4FFFFH) are FFH, the device is assumed to be a blank product, in which no check is made of the passwords.

3. Password string

A string of passwords in the received data are compared with the data in the flash memory. In the following cases, a password error is assumed:

- When the received data does not match the data in the flash memory

4. Handling of password error

When a password error occurs, the device goes to an idle state.

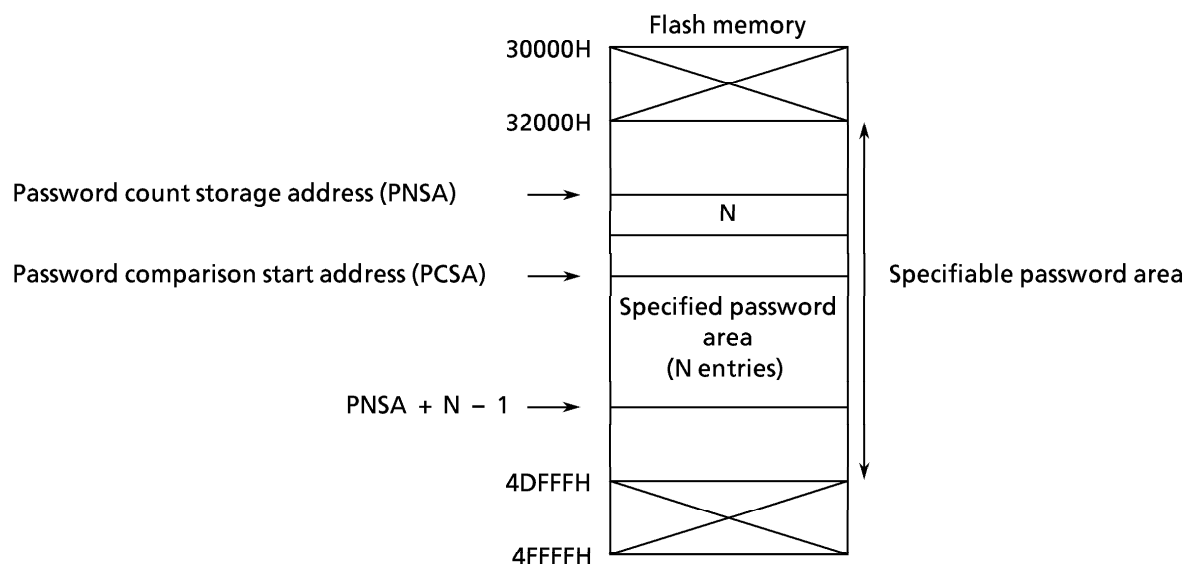
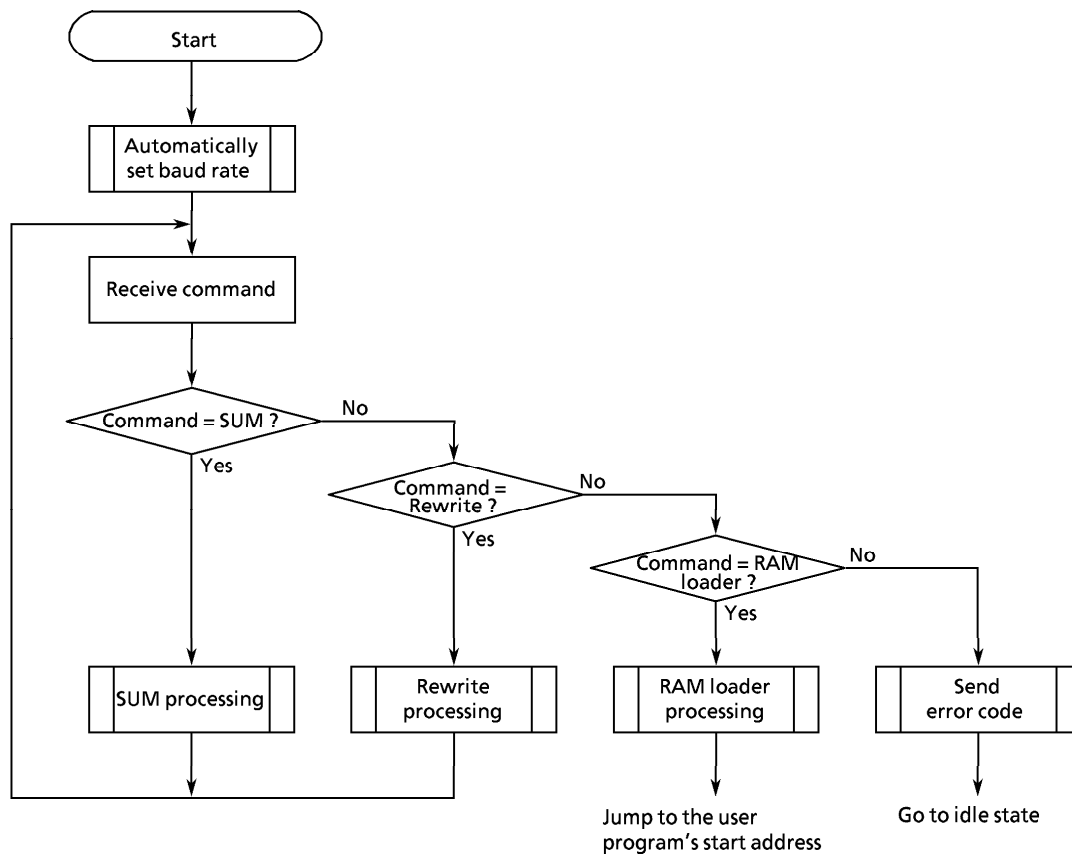
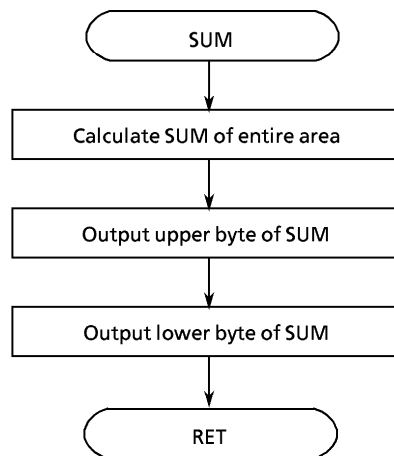


Figure 3.4.3 Conceptual Diagram of a Password Area

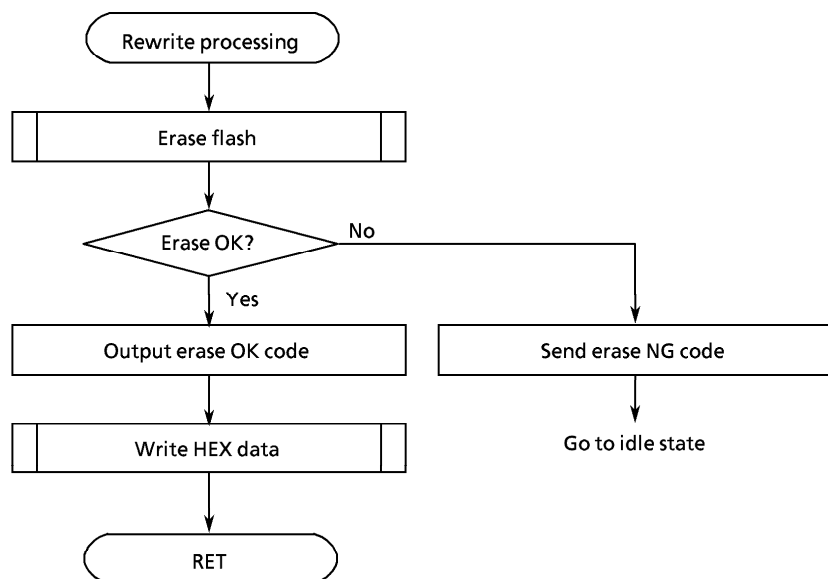
Single Boot General Flow



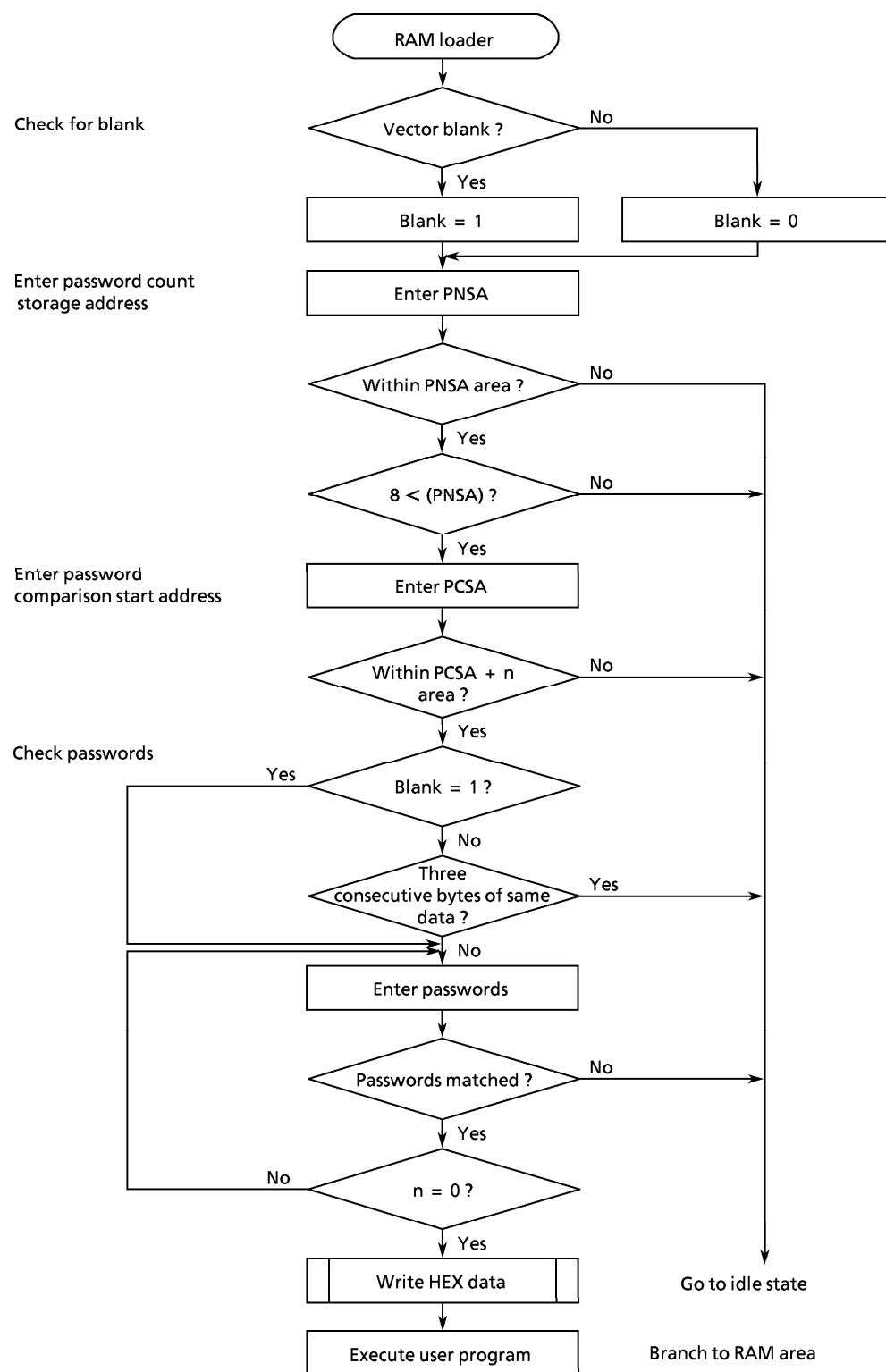
(1) SUM command



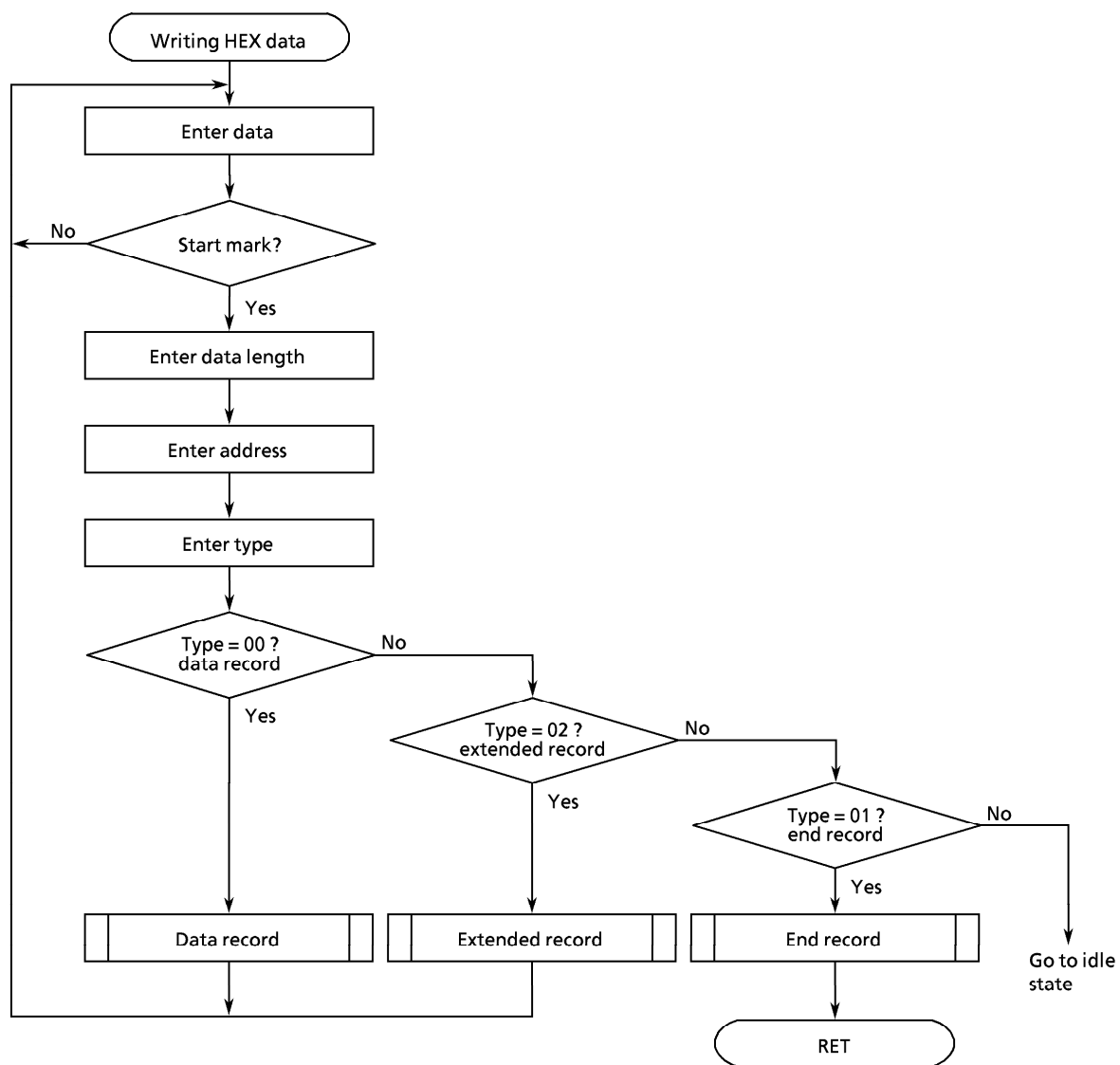
(2) Rewrite command



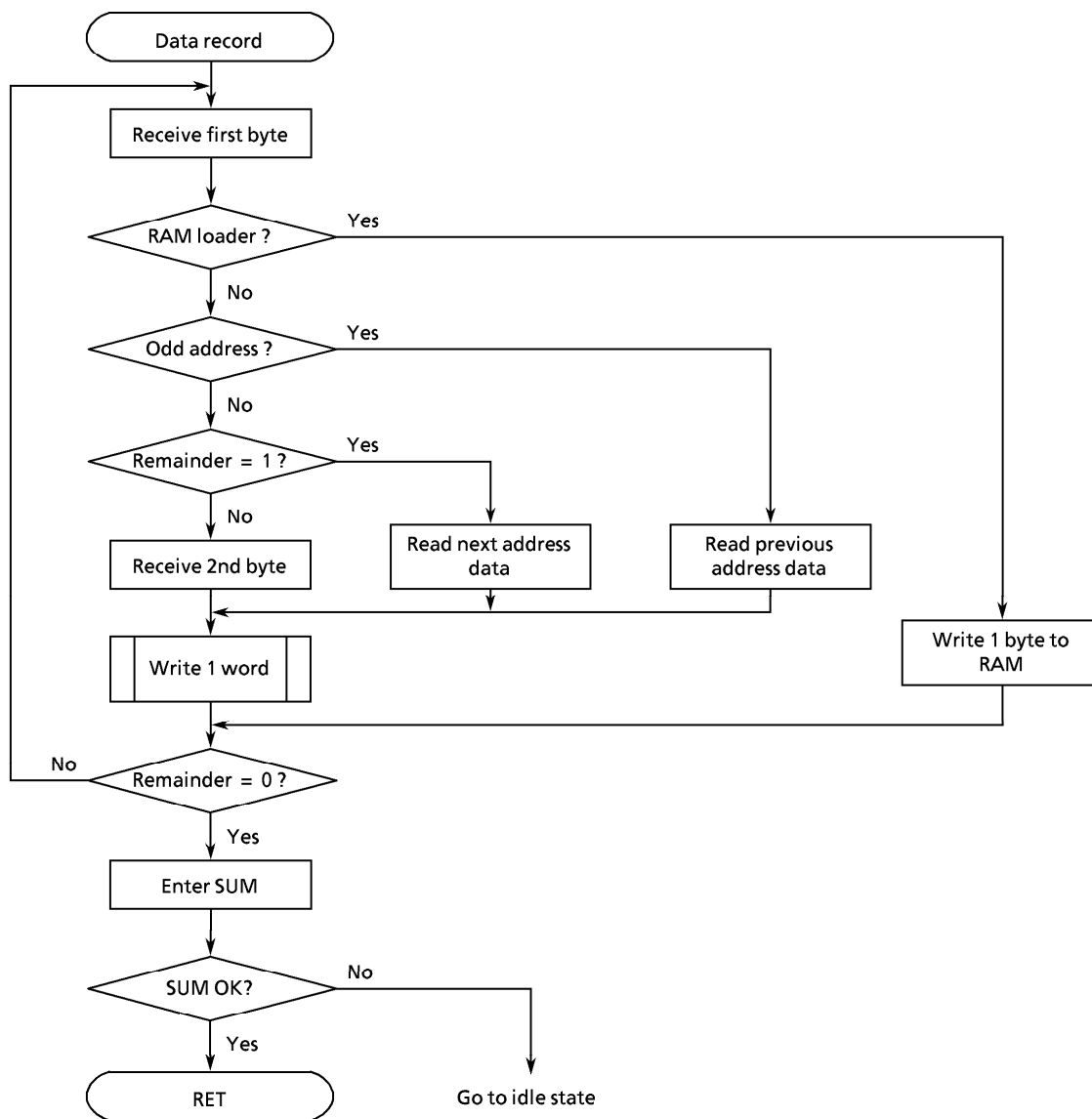
(3)RAM loader command



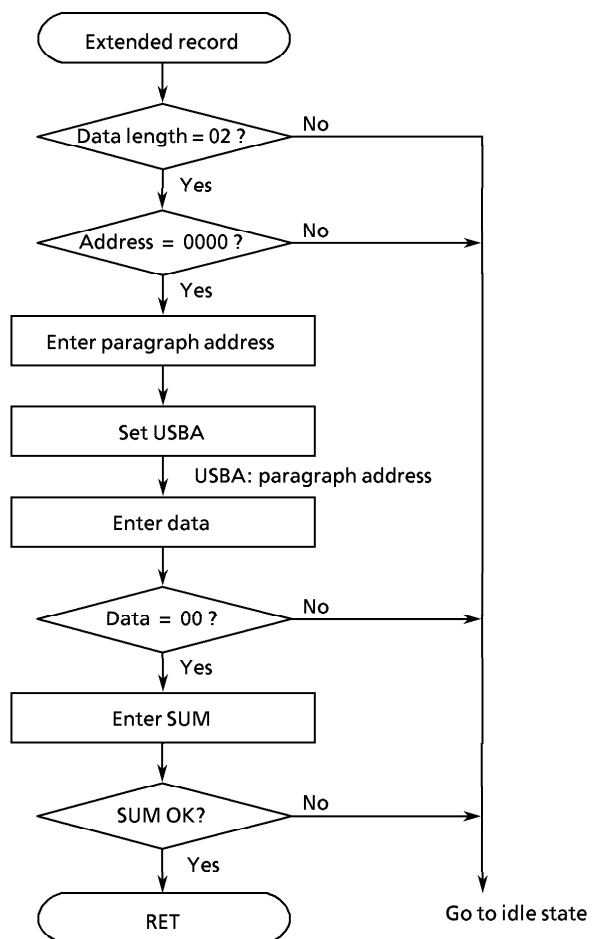
(2)-1 Writing HEX data



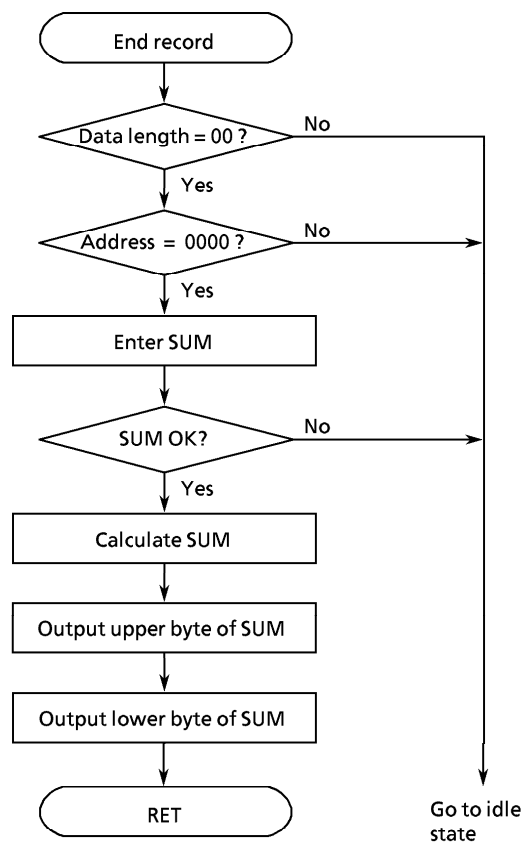
(2)-1-1 Data record



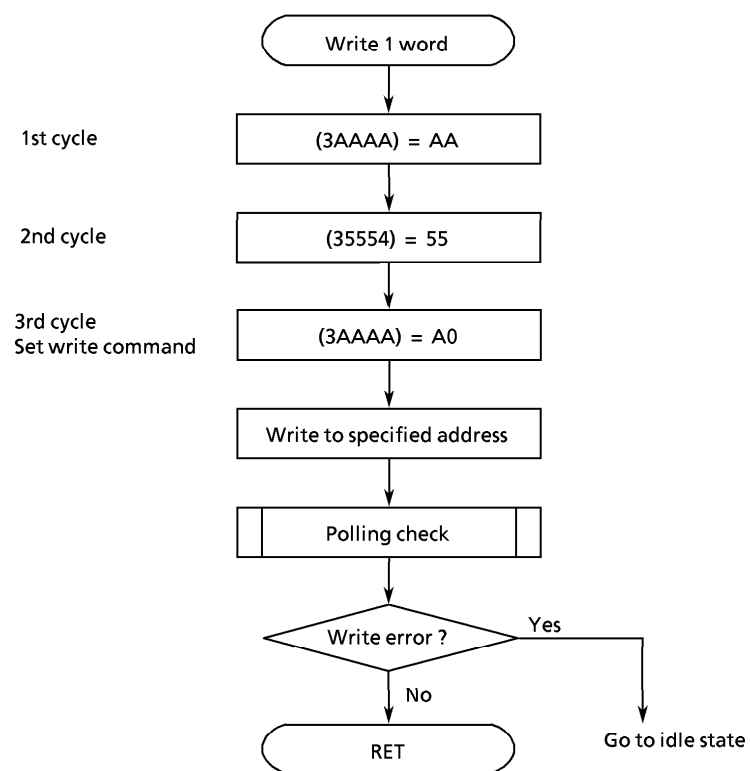
(2)-1-2 Extended record



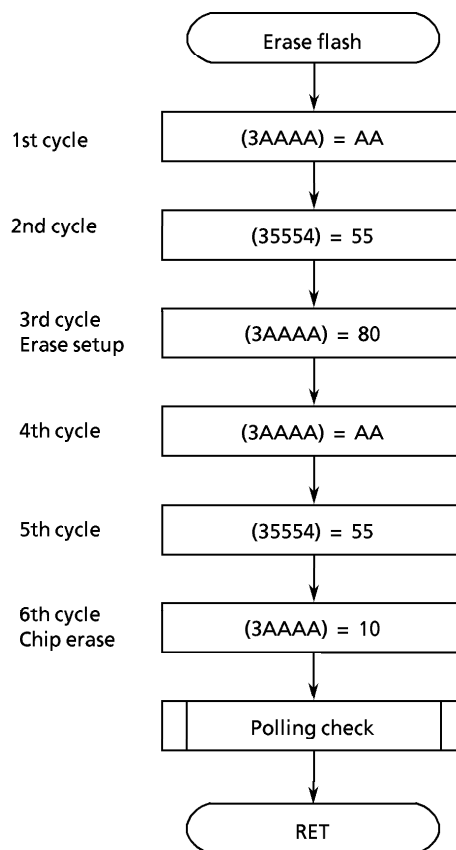
(2)-1-3 End record



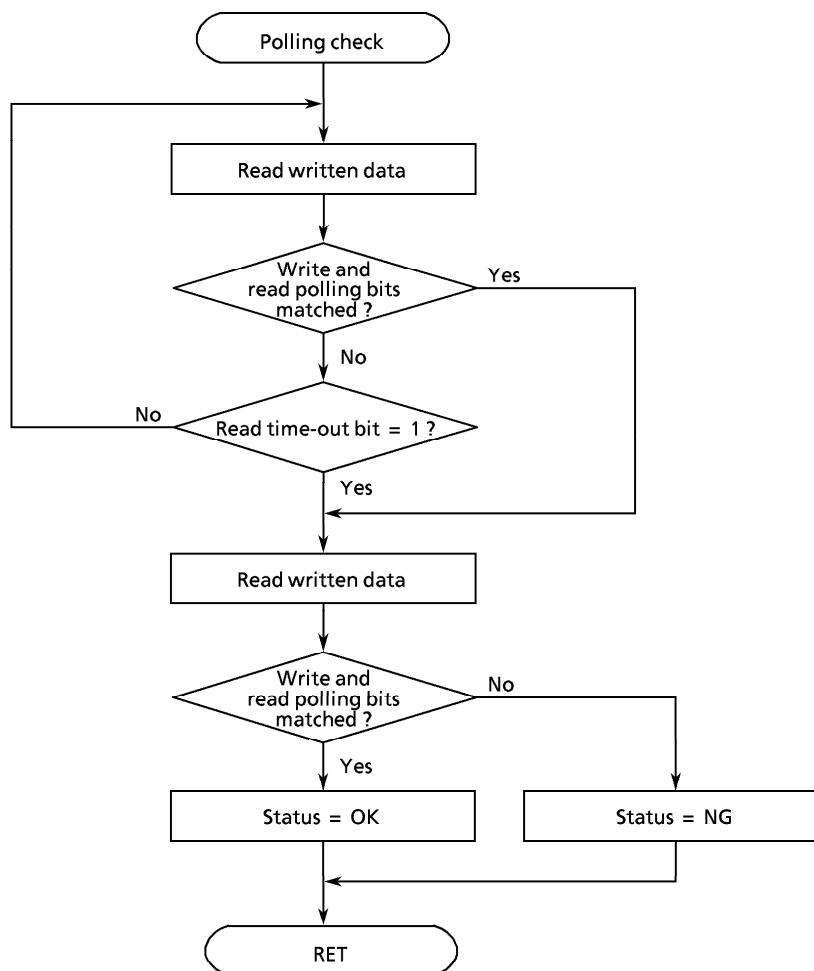
(2)-1-1-1 Writing one word



(2)-2 Flash memory erase



(2)-2-1 Data polling



4. Electrical Characteristics

4.1 Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Power Supply Voltage	V_{CC}	- 0.5 to + 6.5	V
Input Voltage	V_{IN}	- 0.5 to $V_{CC} + 0.5$	V
Output current (total)	ΣI_{OL}	+ 120	mA
Output current (total)	ΣI_{OH}	- 120	mA
Power Dissipation ($T_a = + 85^{\circ}\text{C}$)	P_D	600	mW
Soldering Temperature (10 s)	T_{SOLDER}	+ 260	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	- 55 to + 125	$^{\circ}\text{C}$
Operating Temperature	T_{OPR}	- 40 to + 85	$^{\circ}\text{C}$
Number of Times Program Erased	N_{EW}	1000	Cycle

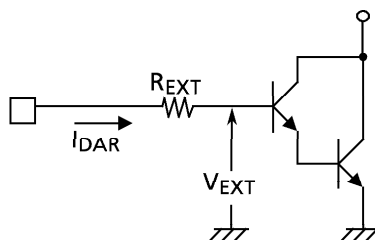
Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

4.2 DC Electrical Characteristics

 $V_{CC} = +5\text{ V} \pm 10\%$, $T_a = -40$ to $+85^\circ\text{C}$ ($f_c = 8$ to 24 MHz)

(single-chip mode, single-boot mode)

Parameter	Symbol	Test Condition	Min	Max	Unit
Input Low Voltage (D0 to 15)	V_{IL}		-0.3	0.8	V
Port 2 to A (except P56, P70, P72, P73, P75)	V_{IL1}		-0.3	$0.3 V_{CC}$	V
RESET, NMI, INT0 to 4	V_{IL2}		-0.3	$0.25 V_{CC}$	V
EA, AM8/16	V_{IL3}		-0.3	0.3	V
X1	V_{IL4}		-0.3	$0.2 V_{CC}$	V
Input High Voltage (D0 to 15)	V_{IH}		2.2	$V_{CC} + 0.3$	V
Port 2 to A (except P56, P70, P72, P73, P75)	V_{IH1}		$0.7 V_{CC}$	$V_{CC} + 0.3$	V
RESET, NMI, INT0 to 4	V_{IH2}		$0.75 V_{CC}$	$V_{CC} + 0.3$	V
EA, AM8/16	V_{IH3}		$V_{CC} - 0.3$	$V_{CC} + 0.3$	V
X1	V_{IH4}		$0.8 V_{CC}$	$V_{CC} + 0.3$	V
Output Low Voltage	V_{OL}	$I_{OL} = 1.6\text{ mA}$		0.45	V
Output High Voltage	V_{OH}	$I_{OH} = -400\text{ }\mu\text{A}$	2.4		V
	V_{OH1}	$I_{OH} = -100\text{ }\mu\text{A}$	$0.75 V_{CC}$		V
	V_{OH2}	$I_{OH} = -20\text{ }\mu\text{A}$	$0.9 V_{CC}$		V
Darlington Drive Current (8 Output Pins max.)	I_{DAR}	$V_{EXT} = 1.5\text{ V}$ $R_{EXT} = 1.1\text{ k}\Omega$	-1.0	-3.5	mA
Input Leakage Current	I_{LI}	$0.0 \leq V_{in} \leq V_{CC}$	0.02 (Typ.)	± 5	μA
Output Leakage Current	I_{LO}	$0.2 \leq V_{in} \leq V_{CC} - 0.2$	0.05 (Typ.)	± 10	μA
NORMAL (at Read)	I_{CC}	$f_c = 24\text{ MHz}$	70 (Typ.)	95	mA
(at Write / Erase)			80 (Typ.)	110	mA
RUN			35 (Typ.)	50	mA
IDLE2			30 (Typ.)	40	mA
IDLE1			5 (Typ.)	10	mA
STOP ($T_a = -40$ to $+85^\circ\text{C}$)		$0.2 \leq V_{in} \leq V_{CC} - 0.2$	0.5 (Typ.)	100	μA
($T_a = -20$ to $+70^\circ\text{C}$)				50	μA
Power Down Voltage (at STOP, RAM Back up)	V_{STOP}	$V_{IL2} = 0.2 V_{CC}$ $V_{IH2} = 0.8 V_{CC}$	2.0	6.0	V
Pull Up Resistance	R_{RP}		45	160	$\text{k}\Omega$
Pin Capacitance	C_{IO}	$f_c = 1\text{ MHz}$		10	pF
Schmitt Width RESET, NMI, INT0 to 4	V_{TH}		0.4	1.0 (Typ.)	V

Note 1: Typical values are for $T_a = +25^\circ\text{C}$, $V_{CC} = +5\text{ V}$ Note 2: I_{DAR} guarantees up to eight pins from any output port.Refer: I_{DAR} definition diagram.

4.3 AC Electrical Characteristics

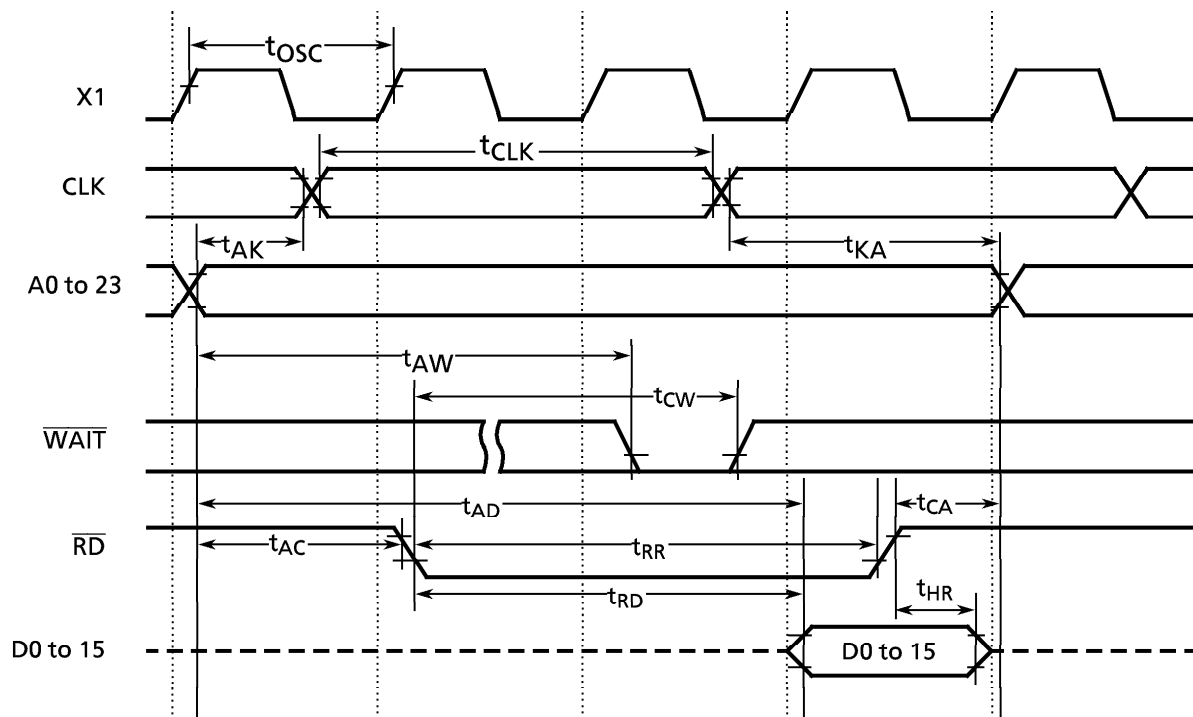
 $V_{CC} = +5\text{ V} \pm 10\%$, $T_a = -40$ to $+85^\circ\text{C}$
(f_c = 8 MHz to 24 MHz)

No.	Parameter	Symbol	Variable		24 MHz		Unit
			Min	Max	Min	Max	
1	Oscillation cycle (= x)	t _{OSC}	42	125	42		ns
2	Clock pulse width	t _{CLK}	2.0x – 40		44		ns
3	A0 to 23 valid → Clock hold	t _{AK}	0.5x – 20		1		ns
4	Clock valid → A0 to 23 hold	t _{KA}	1.5x – 60		3		ns
5	A0 to 23 valid → $\overline{\text{RD}}/\overline{\text{WR}}$ fall	t _{AC}	1.0x – 20		22		ns
6	$\overline{\text{RD}}/\overline{\text{WR}}$ rise → A0 to 23 hold	t _{CA}	0.5x – 20		1		ns
7	A0 to 23 valid → D0 to 15 input	t _{AD}		3.5x – 40		107	ns
8	$\overline{\text{RD}}$ fall → D0 to 15 input	t _{RD}		2.5x – 45		60	ns
9	$\overline{\text{RD}}$ low pulse width	t _{RR}	2.5x – 40		65		ns
10	$\overline{\text{RD}}$ rise → D0 to 15 hold	t _{HR}	0		0		ns
11	$\overline{\text{WR}}$ low pulse width	t _{WW}	2.5x – 40		65		ns
12	D0 to 15 valid → $\overline{\text{WR}}$ rise	t _{DW}	2.0x – 40		44		ns
13	$\overline{\text{WR}}$ rise → D0 to 15 hold	t _{WD}	0.5x – 10		11		ns
14	A0 to 23 valid → $\overline{\text{WAIT}}$ input $\left(\begin{smallmatrix} 1 \text{ WAIT} \\ + n \text{ mode} \end{smallmatrix} \right)$	t _{AW}		3.5x – 90		57	ns
	A0 to 23 valid → $\overline{\text{WAIT}}$ input $\left(\begin{smallmatrix} 0 + n \text{ WAIT} \\ \text{mode} \end{smallmatrix} \right)$	t _{AW}		1.5x – 40		23	ns
15	$\overline{\text{RD}}/\overline{\text{WR}}$ fall → $\overline{\text{WAIT}}$ hold $\left(\begin{smallmatrix} 1 \text{ WAIT} \\ + n \text{ mode} \end{smallmatrix} \right)$	t _{CW}	2.5x + 0		105		ns
	$\overline{\text{RD}}/\overline{\text{WR}}$ fall → $\overline{\text{WAIT}}$ hold $\left(\begin{smallmatrix} 0 + n \text{ WAIT} \\ \text{mode} \end{smallmatrix} \right)$	t _{CW}	0.5x + 0		21		ns
16	$\overline{\text{WR}}$ rise → PORT valid	t _{CP}		200		200	ns

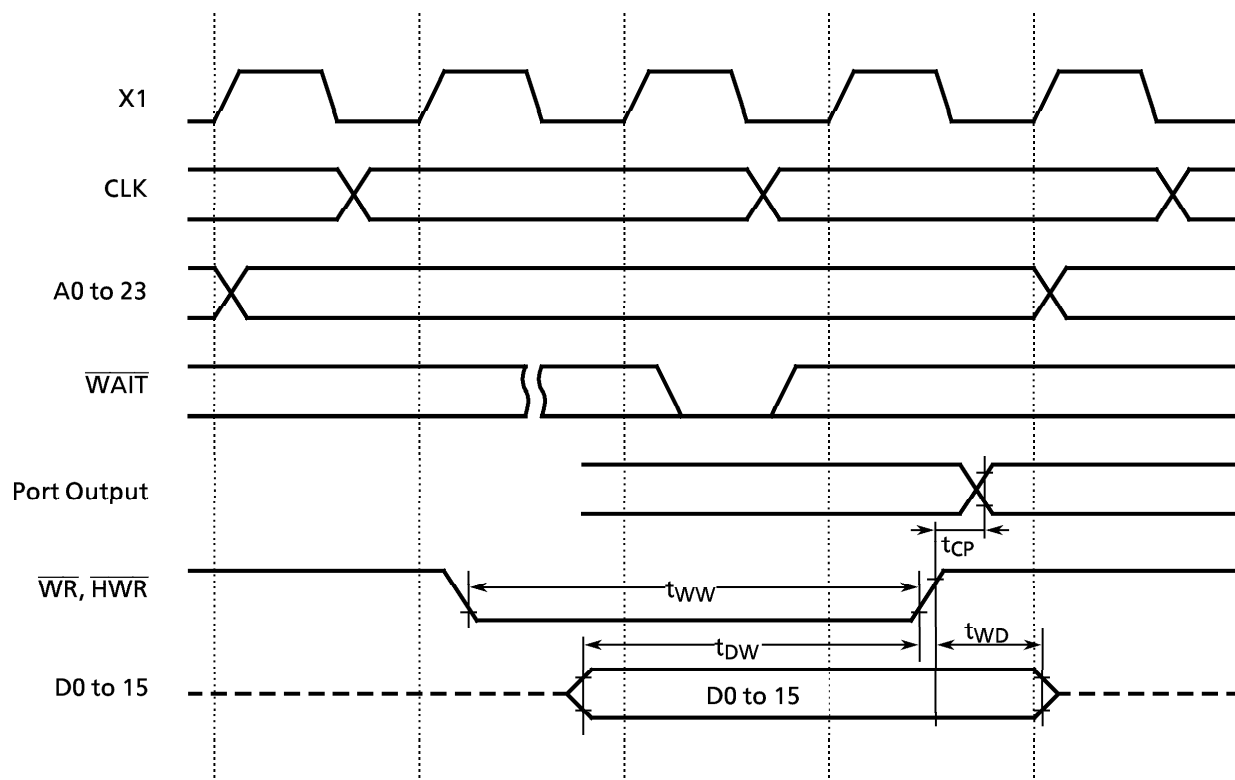
AC measuring conditions

- Output level: High 2.2 V / Low 0.8 V, CL = 50 pF
- Input level: High 2.4 V / Low 0.45 V (D0 to D15)
High $0.8 \times V_{CC}$ / Low $0.2 \times V_{CC}$ (except for D0 to D15)

(1) Read cycle



(2) Write cycle



4.4 Serial Channel Timing

(1) I/O interface mode

① SCLK input mode

$V_{CC} = +5V \pm 10\%$, $T_a = -40$ to $+85^\circ\text{C}$ ($f_c = 8$ to 24 MHz)

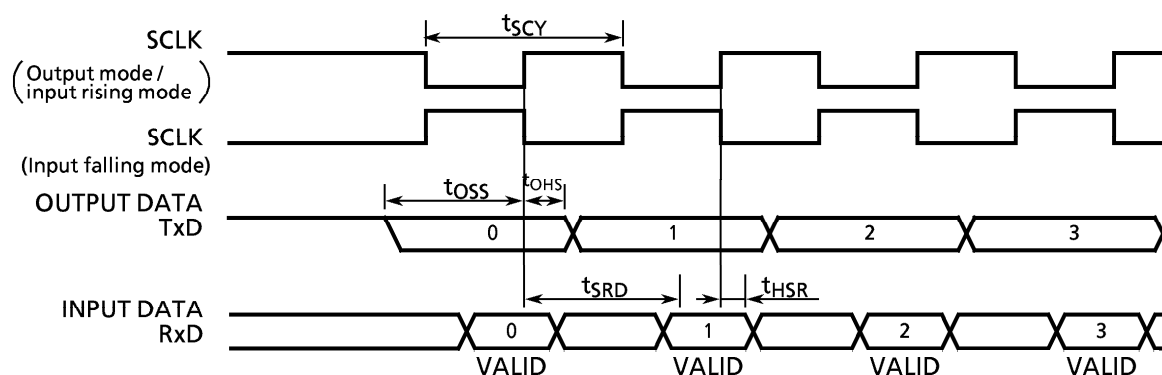
Parameter	Symbol	Variable		24 MHz		Unit
		Min	Max	Min	Max	
SCLK cycle	t_{SCY}	16x		0.667		μs
Output Data \rightarrow SCLK rise/fall*	t_{OSS}	$t_{SCY}/2 - 5x - 50$		75		ns
SCLK rise/fall* \rightarrow Output Data hold	t_{OHS}	$5x - 100$		108		ns
SCLK rise/fall* \rightarrow input data hold	t_{HSR}	0		0		ns
SCLK rise/fall* \rightarrow valid data input	t_{SRD}		$t_{SCY} - 5x - 100$		358	ns

*) SCLK rise/fall: In SCLK rising edge mode, SCLK rising edge timing; in SCLK falling edge mode, SCLK falling edge timing

② SCLK output mode

$V_{CC} = +5V \pm 10\%$, $T_a = -40$ to $+85^\circ\text{C}$ ($f_c = 8$ to 24 MHz)

Parameter	Symbol	Variable		24 MHz		Unit
		Min	Max	Min	Max	
SCLK cycle (programmable)	t_{SCY}	16x	8192x	0.667	341.3	μs
Output Data \rightarrow SCLK rising edge	t_{OSS}	$t_{SCY} - 2x - 150$		433		ns
SCLK rising edge \rightarrow Output Data hold	t_{OHS}	$2x - 80$		3		ns
SCLK rising edge \rightarrow Input Data hold	t_{HSR}	0		0		ns
SCLK rising edge \rightarrow valid data input	t_{SRD}		$t_{SCY} - 2x - 150$		433	ns



(2) UART mode (SCLK0 to 1 external input)

$V_{CC} = +5V \pm 10\%$, $T_a = -40$ to $+85^\circ\text{C}$ ($f_c = 8$ to 24 MHz)

Parameter	Symbol	Variable		24 MHz		Unit
		Min	Max	Min	Max	
SCLK cycle	t_{SCY}	$4x + 20$		187		ns
Low-level SCLK pulse width	t_{SCYL}	$2x + 5$		88		ns
High-level SCLK pulse width	t_{SCYH}	$2x + 5$		88		ns

4.5 AD Conversion Characteristics

 $V_{CC} = +5\text{ V} \pm 10\%$, $T_a = -40$ to $+85^\circ\text{C}$ ($f_c = 8$ to 24 MHz)

Parameter		Symbol	Test Conditions	Min	Typ.	Max	Unit
AD analog reference supply voltage (+)		V_{REFH}		$V_{CC} - 0.2$		V_{CC}	V
AD analog reference supply voltage (-)		V_{REFL}		V_{SS}		$V_{SS} + 0.2$	
Analog reference voltage		AV_{CC}		$V_{CC} - 0.2$		V_{CC}	
Analog reference voltage		AV_{SS}		V_{SS}		$V_{SS} + 0.2$	
Analog input voltage		V_{AIN}		V_{REFL}		V_{REFH}	
Analog reference voltage supply current	$\langle V_{REFON} \rangle = 1$	I_{REF}	$V_{CC} = +5\text{ V} \pm 10\%$			3.7	mA
	$\langle V_{REFON} \rangle = 0$		$V_{CC} = +5\text{ V} \pm 10\%$		0.02	5.0	μA
Total tolerance (excludes quantization error)		E_T	$V_{CC} = +5\text{ V} \pm 10\%$		± 1	± 3	LSB

Note 1: $1\text{LSB} = (V_{REFH} - V_{REFL}) / 2^{10} [\text{V}]$ Note 2: Power supply current I_{CC} from the VCC pin includes the power supply current from the AVCC pin.

4.6 Event Counter (External Input Clocks: T10, T14, T18, T19, T1A, T1B)

 $V_{CC} = +5\text{ V} \pm 10\%$, $T_a = -40$ to $+85^\circ\text{C}$ ($f_c = 8$ to 24 MHz)

Parameter	Symbol	Variable		24 MHz		Unit
		Min	Max	Min	Max	
External input clock cycle	t_{VCK}	$8x + 100$		433		ns
External low-level input clock pulse width	t_{VCKL}	$4x + 40$		207		ns
External high-level input clock pulse width	t_{VCKH}	$4x + 40$		207		ns

4.7 Interrupt Operation

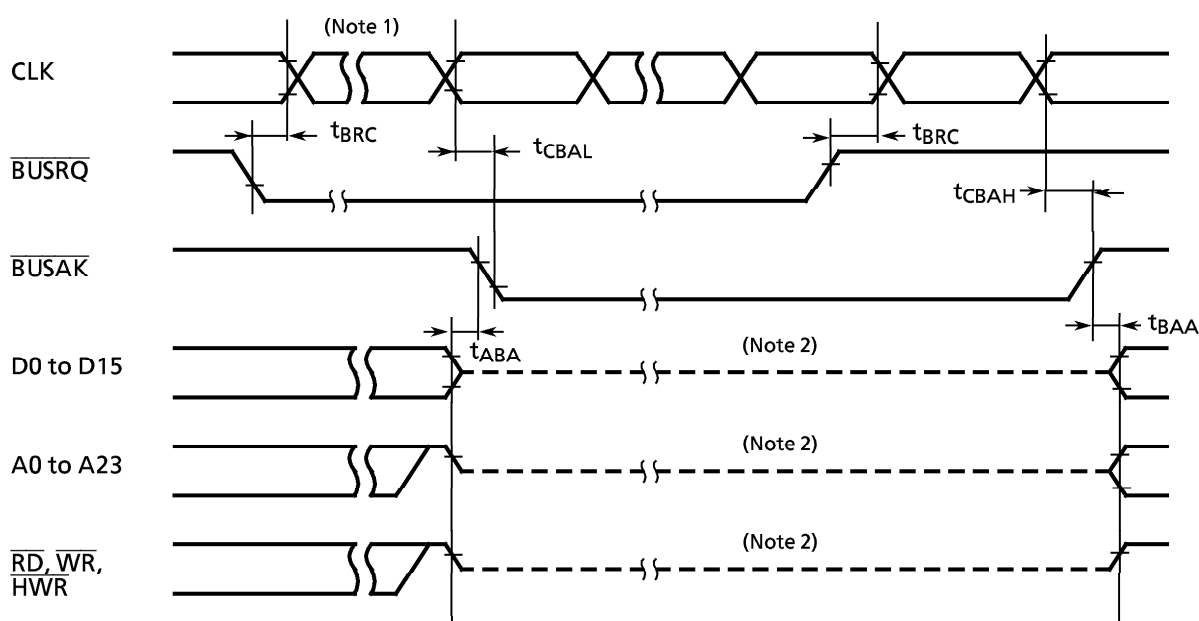
 $V_{CC} = +5\text{ V} \pm 10\%$, $T_a = -40$ to $+85^\circ\text{C}$ ($f_c = 8$ to 24 MHz)

Parameter	Symbol	Variable		24 MHz		Unit
		Min	Max	Min	Max	
NMI, INT0 to 4 low-level pulse width	t_{INTAL}	$4x$		167		ns
NMI, INT0 to 4 high-level pulse width	t_{INTAH}	$4x$		167		ns
INT5 to INT8 low-level pulse width	t_{INTBL}	$8x + 100$		433		ns
INT5 to INT8 high-level pulse width	t_{INTBH}	$8x + 100$		433		ns

4.8 Bus Request/Bus Acknowledge Timing

 $V_{CC} = +5V \pm 10\%$, $T_a = -40$ to $+85^\circ\text{C}$ ($f_c = 8$ to 24 MHz)

Parameter	Symbol	Variable		24 MHz		Unit
		Min	Max	Min	Max	
BUSRQ setup time for CLK	t_{BRC}	120		120		ns
CLK \rightarrow BUSAK fall	t_{CBAL}		$2.0x + 120$		203	ns
CLK \rightarrow BUSAK rise	t_{CBAH}		$0.5x + 40$		61	ns
Time from output buffer off until BUSAK falling edge	t_{ABA}	0	80	0	80	ns
Time from BUSAK rising edge until output buffer on	t_{BAA}	0	80	0	80	ns



Note 1: When $\overline{\text{BUSRQ}}$ goes to low level to request bus release, if the current bus cycle is yet complete due to a wait, the bus is not released until the wait completes.

Note 2: The dotted line indicates only that the output buffer is off, not that the signal is at middle level. Immediately after bus release, the signal level prior to the bus release is held dynamically by the external load capacitance. Therefore, designs should allow for the fact that when using an external resistor or similar to fix the signal level while the bus is released, after bus release a delay occurs before the signal goes to its fixed level (due to the CR time constant). The internal programmable pull-up resistor continues to function in accordance with the internal signal level.

